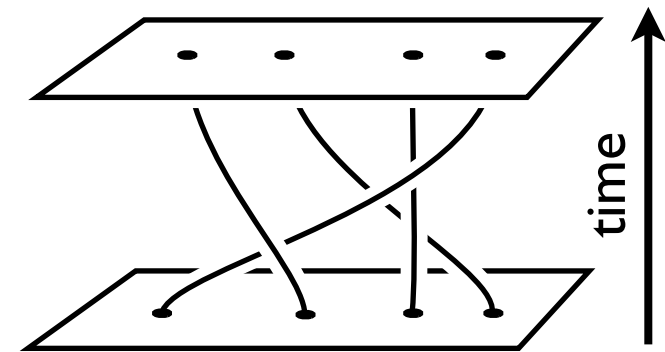
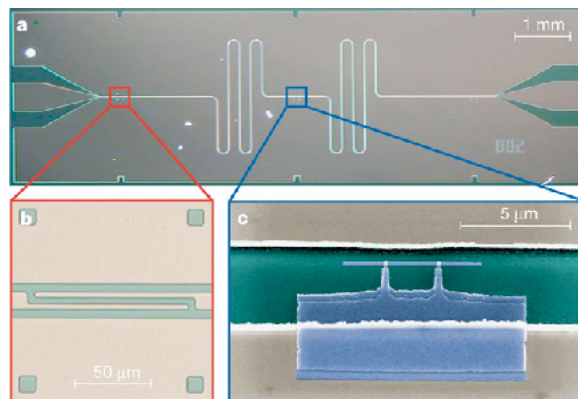
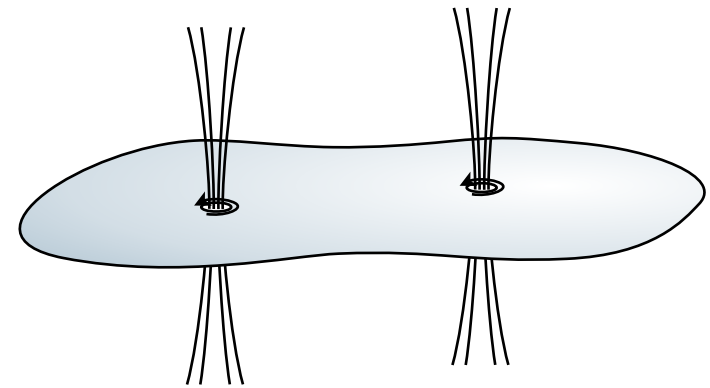
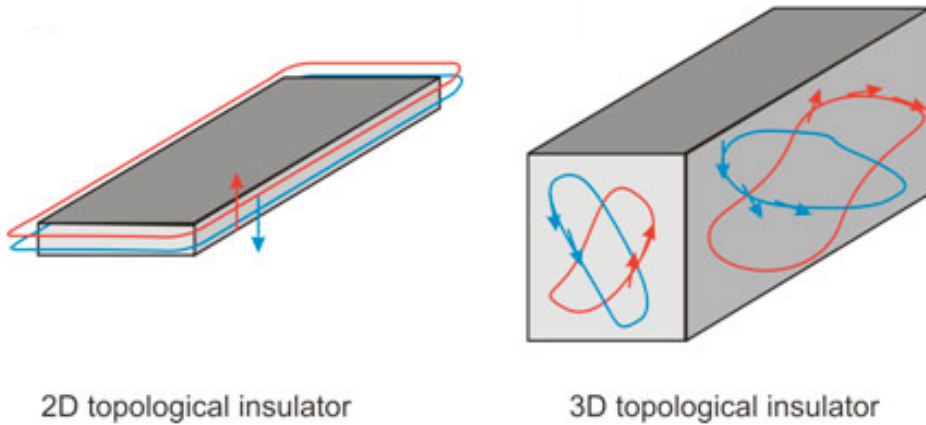


# News from NBIA

## Condensed Matter Physics: from new materials to quantum technology

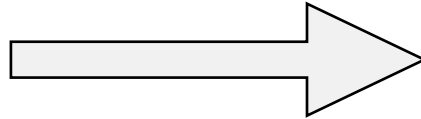
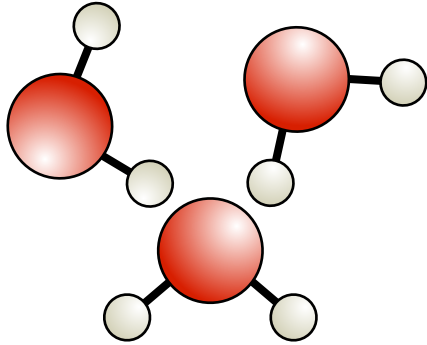
Mark Rudner





# Collective behavior unlike that of individual constituents

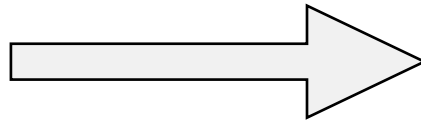
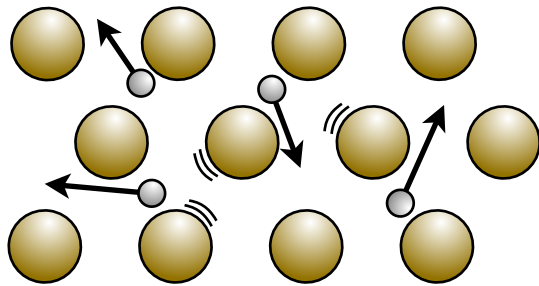
Water molecules



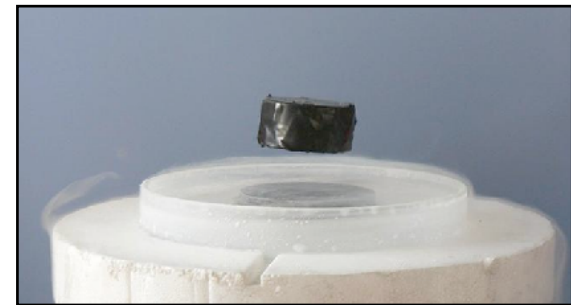
Ocean waves



Electrons in a crystal



Superconductivity



“For theoretical discoveries of topological phase transitions and topological phases of matter”



David Thouless  
(U. Washington)



Duncan Haldane  
(Princeton)



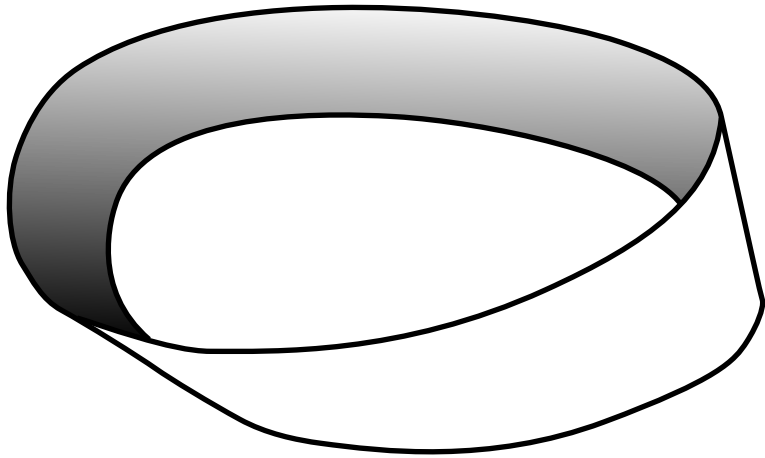
Michael Kosterlitz  
(Brown)



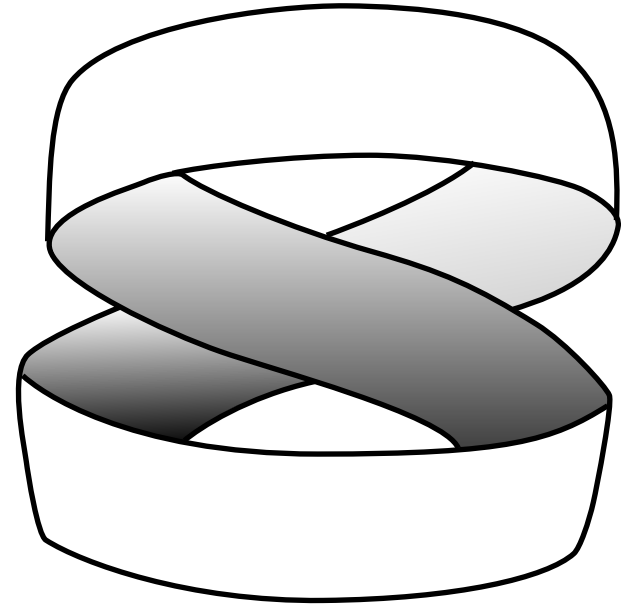
Nobel prize, 2016



Topologically distinct objects cannot be smoothly interconverted

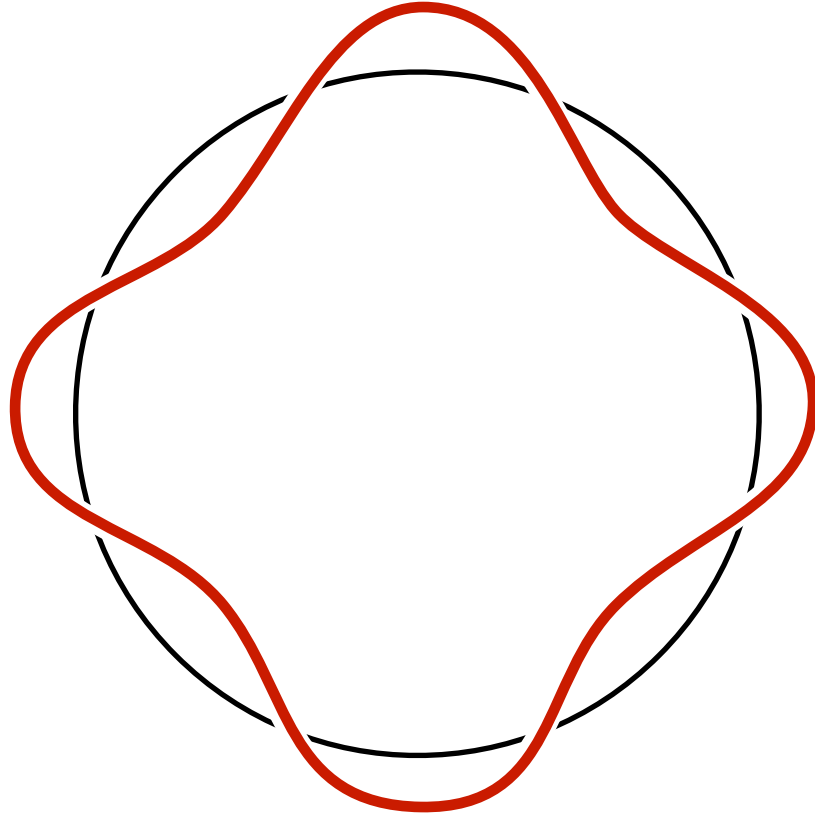


Simple Loop

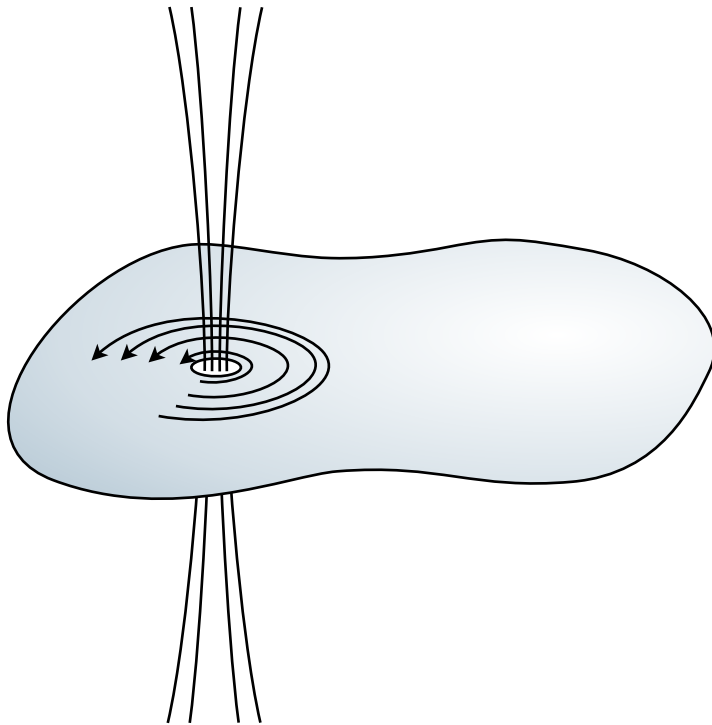


Twisted Strip

Bohr model: wave must “catch its tail” going around a ring,  
number of wavelengths is quantized and topological

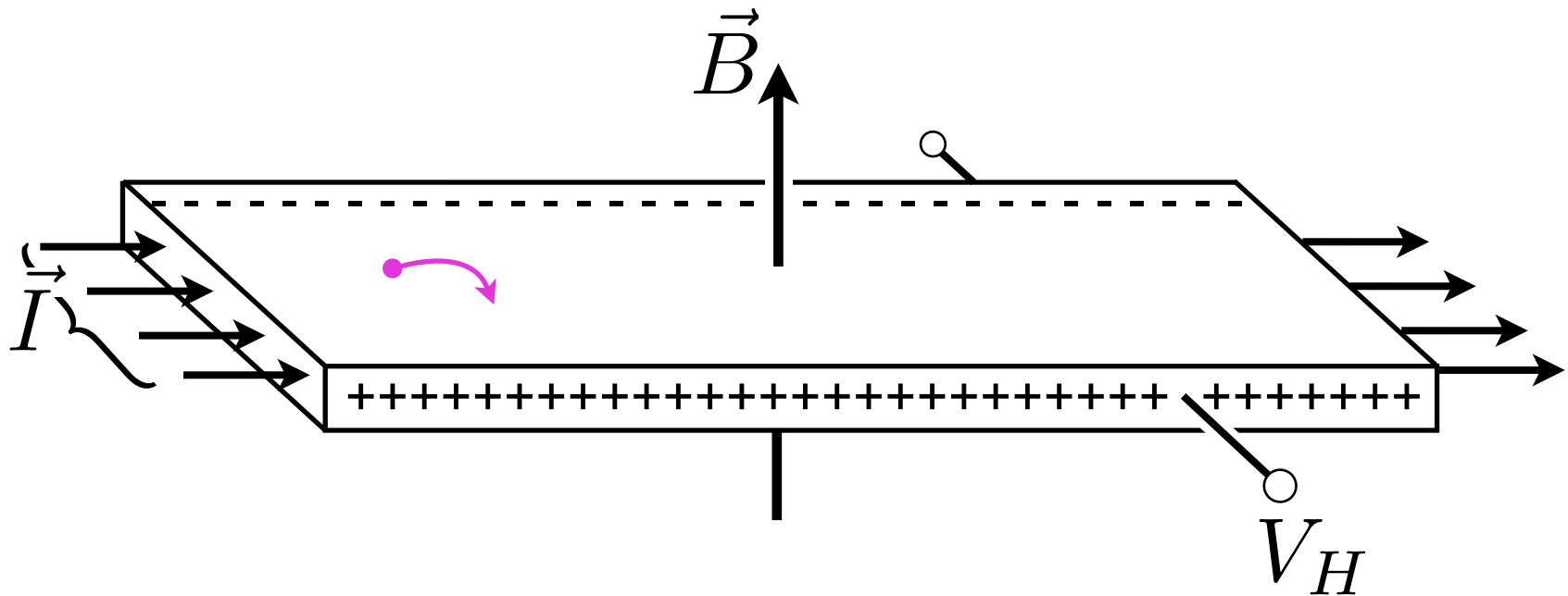


# Vortices in superconductors: “quantum whirlpools”



✦ Kosterlitz + Thouless: vortices crucial for phase transition in 2D

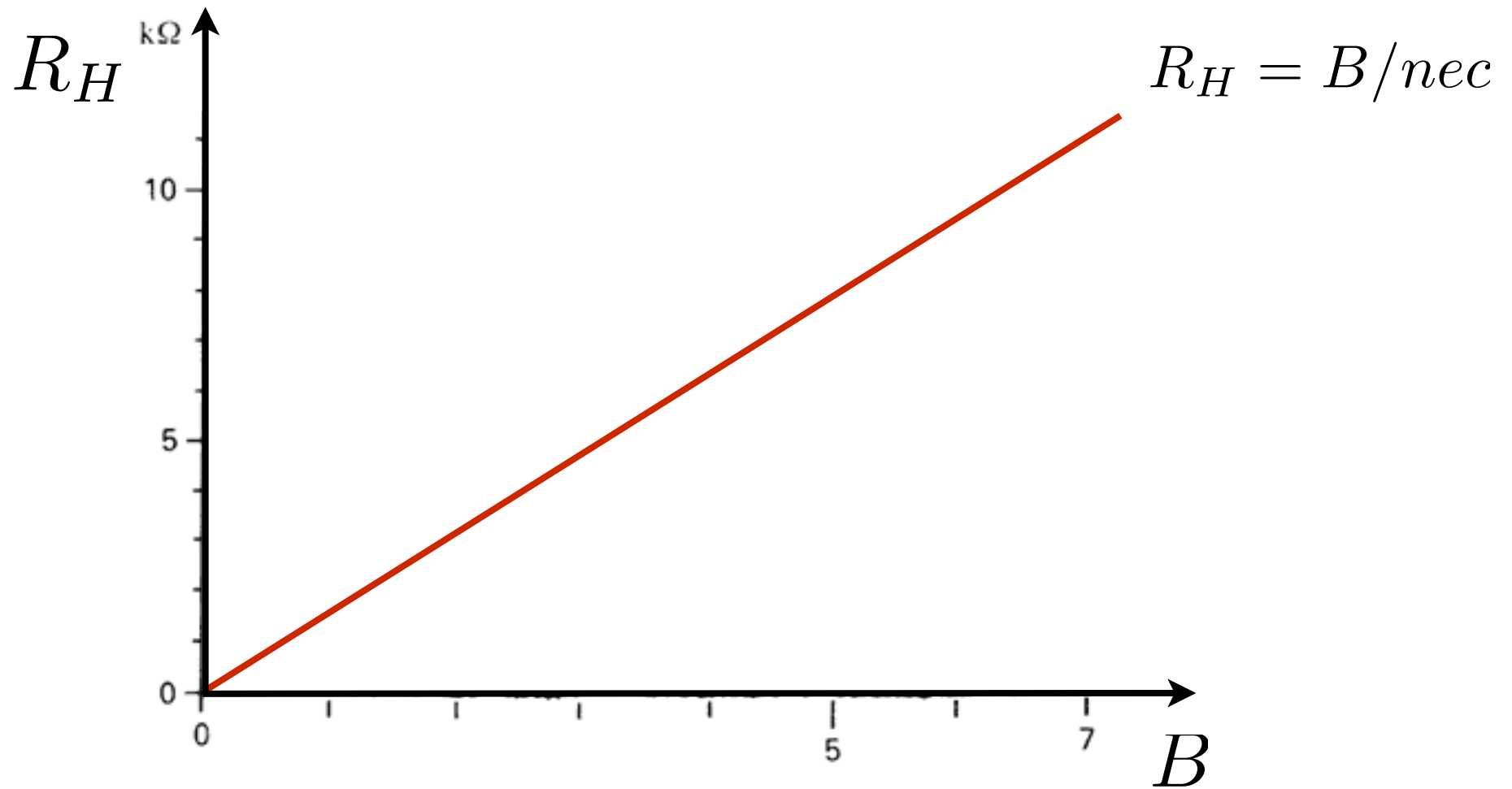
Hall effect: out-of-plane magnetic field generates voltage transverse to applied current



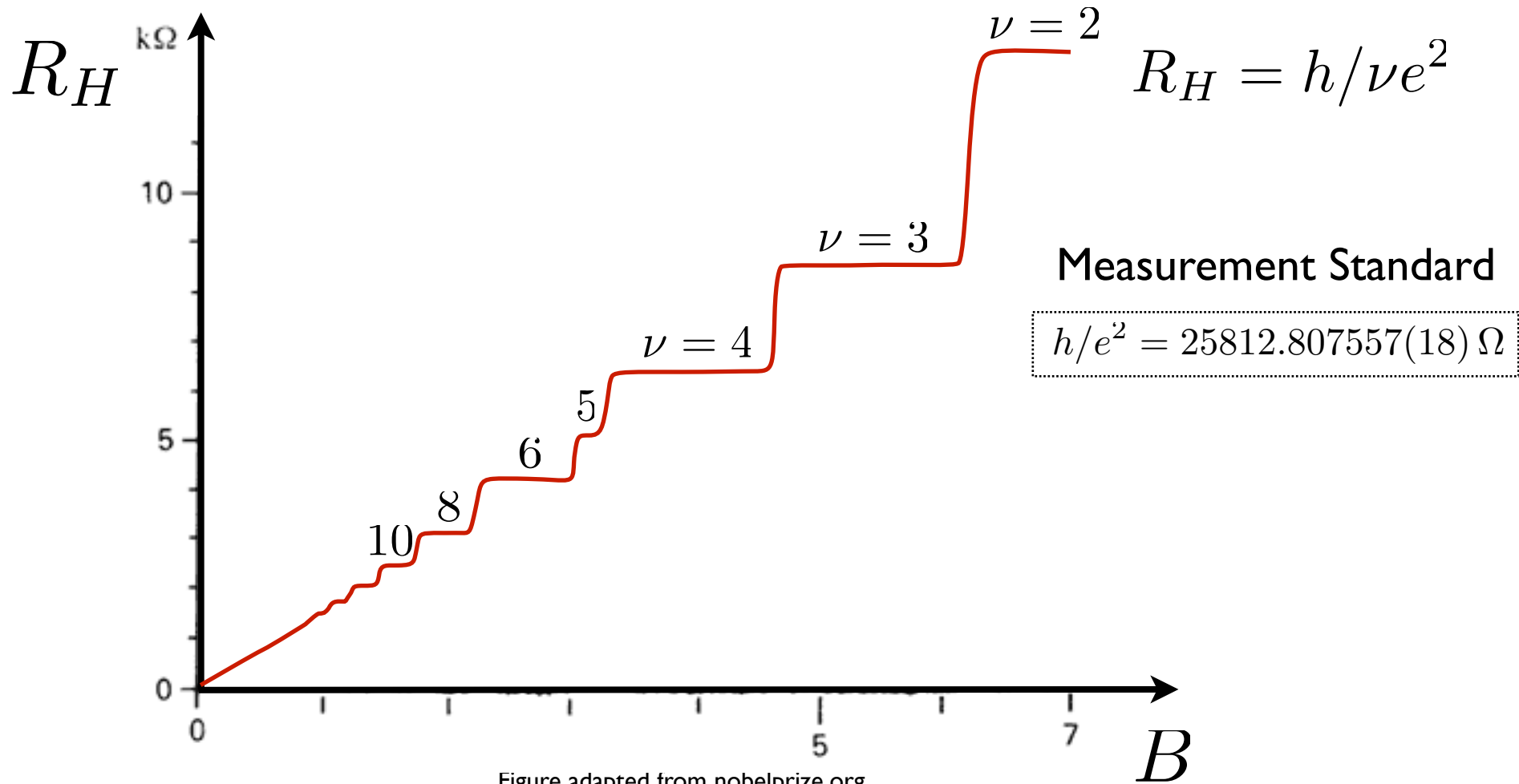
$$R_H \equiv V_H / I$$



Classically, Hall resistance is proportional to  $B$



# Hall resistance features extremely flat steps at low T, high B



# Hall resistance features extremely flat steps at low T, high B

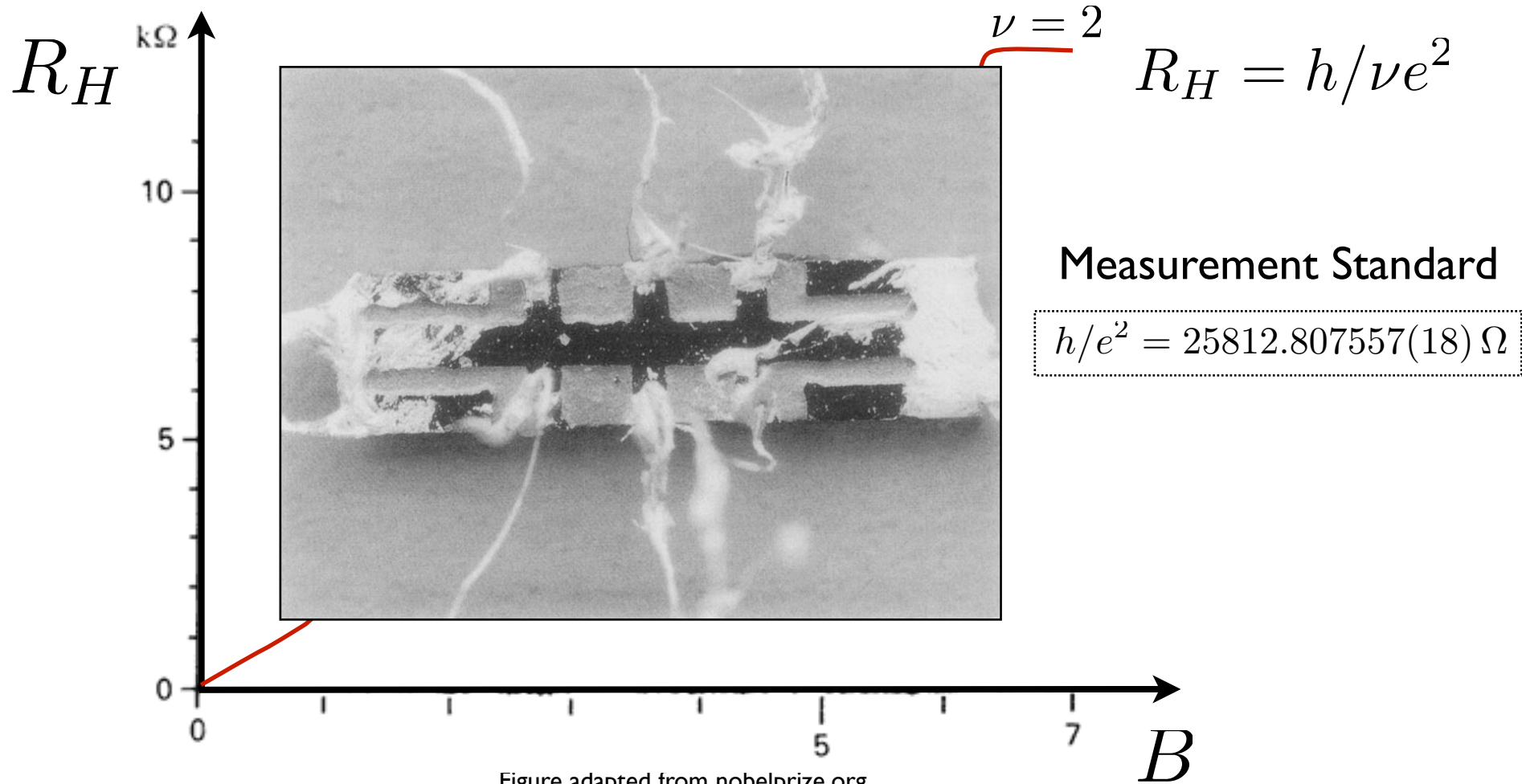


Figure adapted from nobelprize.org

Key theoretical insight, linking robustness to topology:

D. J. Thouless, M. Kohmoto, M. P. Nightingale, and M. den Nijs, Phys. Rev. Lett. **49**, 405 (1982).

Let's play a game: conductor or insulator?

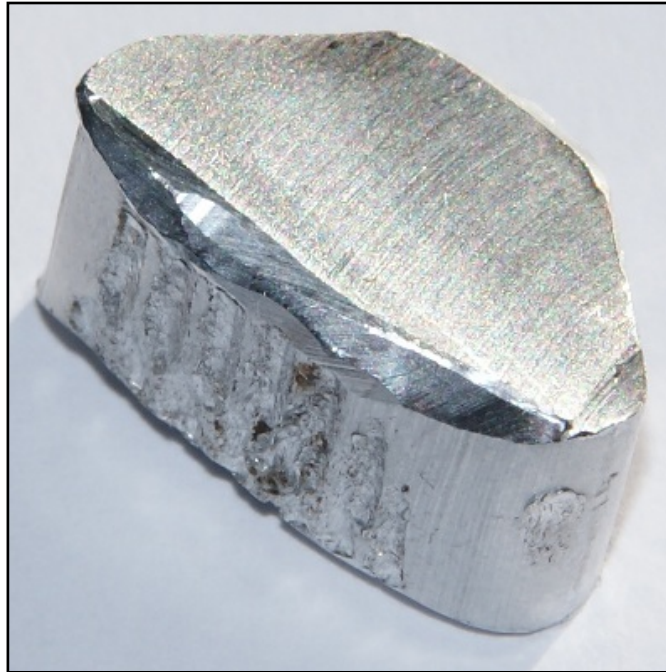


Image from: [images-of-elements.com](https://www.images-of-elements.com)



Let's play a game: conductor or insulator?

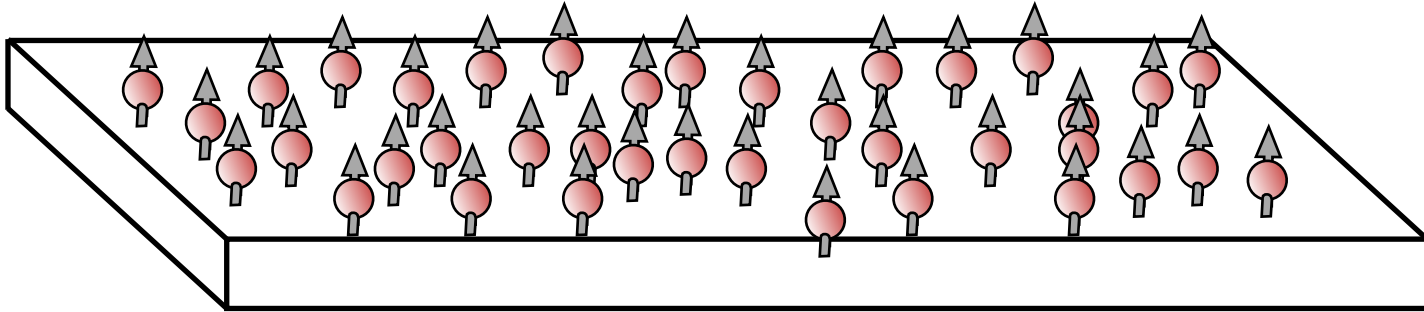


Let's play a game: conductor or insulator?

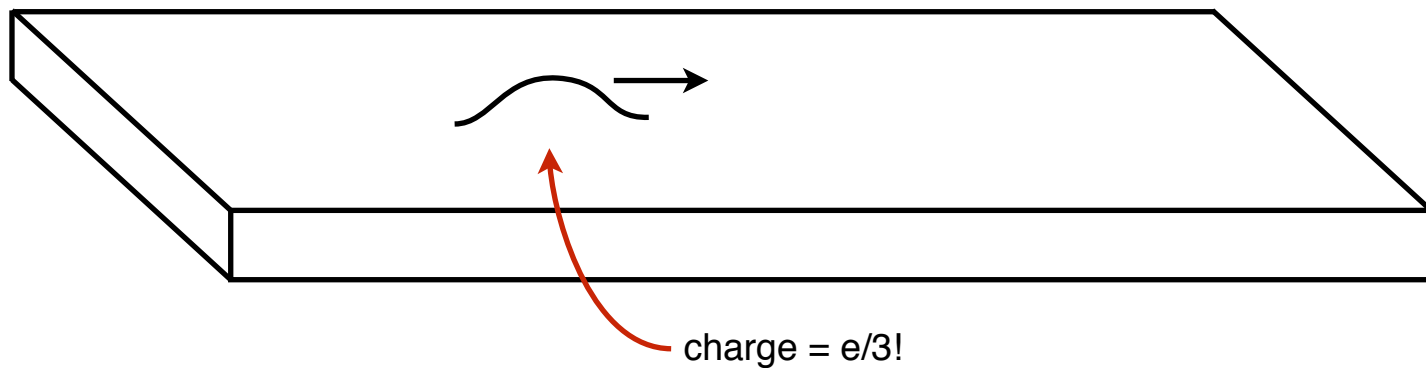
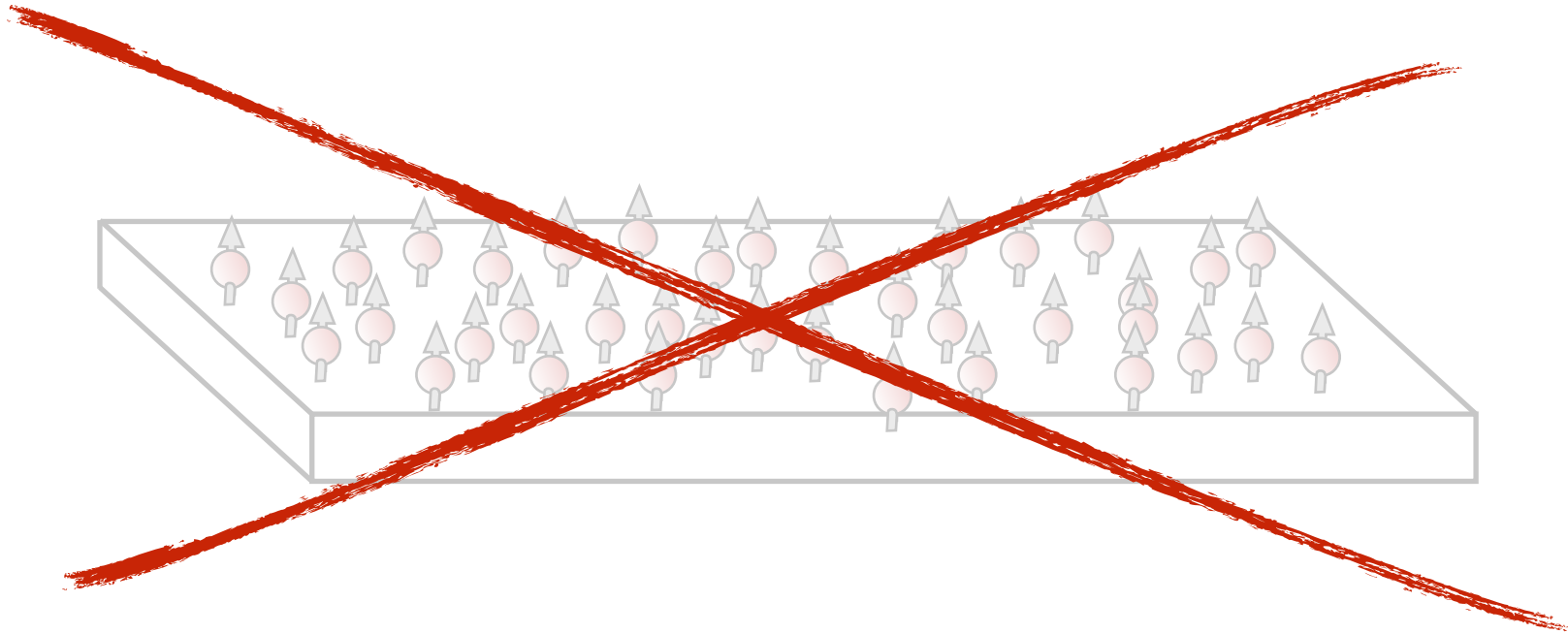


Image from: [www.sttic.com.ru](http://www.sttic.com.ru)

New states with *fractional* values of  $\nu$ : “split” the electron!



New states with *fractional* values of  $\nu$ : “split” the electron!



Opportunities to discover new fundamental particles, in tabletop experiments!



We aim to understand the “dance” of the electrons



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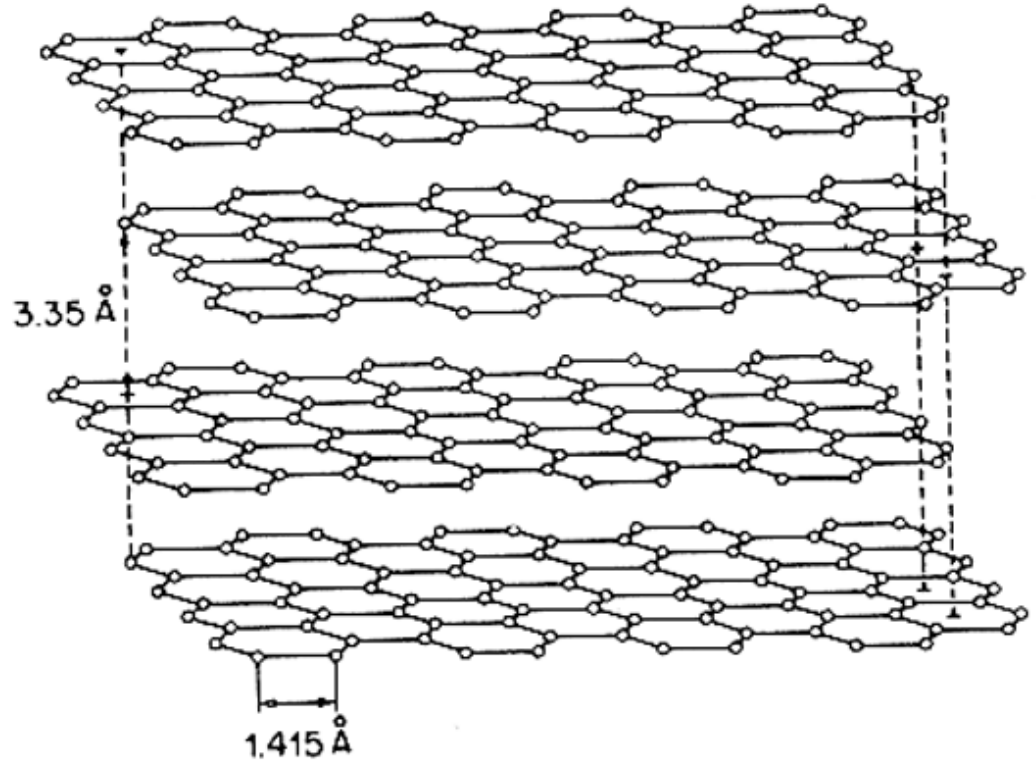




We aim to understand the “dance” of the electrons



# Graphite: stacked 2D sheets of carbon



- \* Strong in-plane bonds, weak interaction between planes



# Graphite: stacked 2D sheets of carbon



$A \text{ is } 5 + B \text{ is } D + C \text{ is } 5 + D \text{ is } D$   
 $19 \quad 19 \quad 19 \quad 19$   
 When  $x = y$

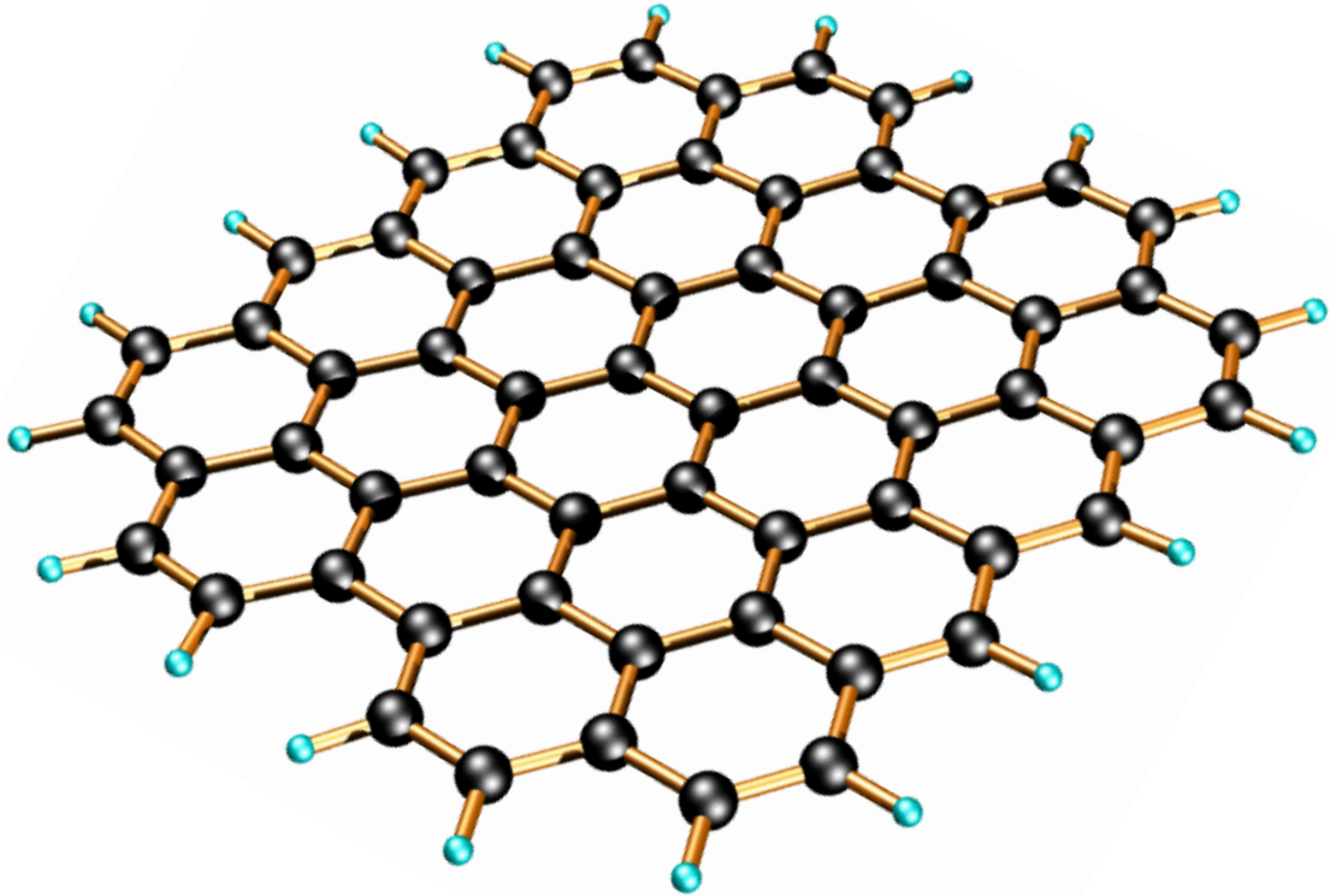
$A = 5 - B$      $B = 5 + D$      $C = 5 - D$      $D = 5 + D$      $A = 5 + B$   
 $19 - 19 \text{ is } 5$      $19 + 19$      $19 - 19$      $19 + 19$      $19 - 19 + 19$

$5 = 2x + 9y$   
 $D = 2x - 9y$

$A \text{ is } D + D \text{ is } D$   
 $19 \quad 19$   
 $19 + 19$   
 $19$

$A \text{ is } D + D \text{ is } D$   
 $19 + 19 \quad 19 + 19$   
 $A = 1 \quad A = 1$   
 $19 \quad 19 + 19$   
 $D = 5$

Graphene: a single atomic plane of carbon



# Exfoliation (Scotch tape) preparation protocol

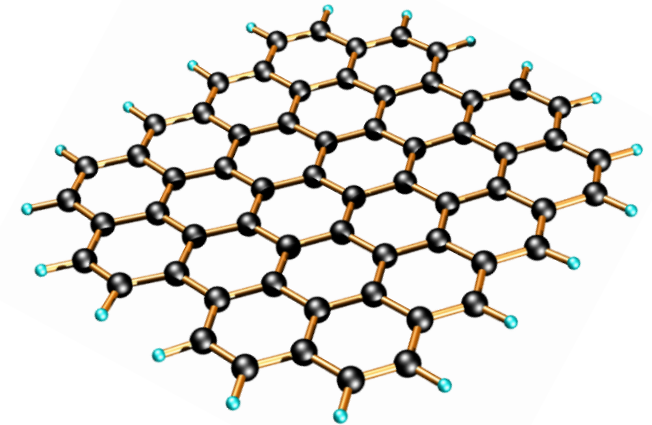
Step 1



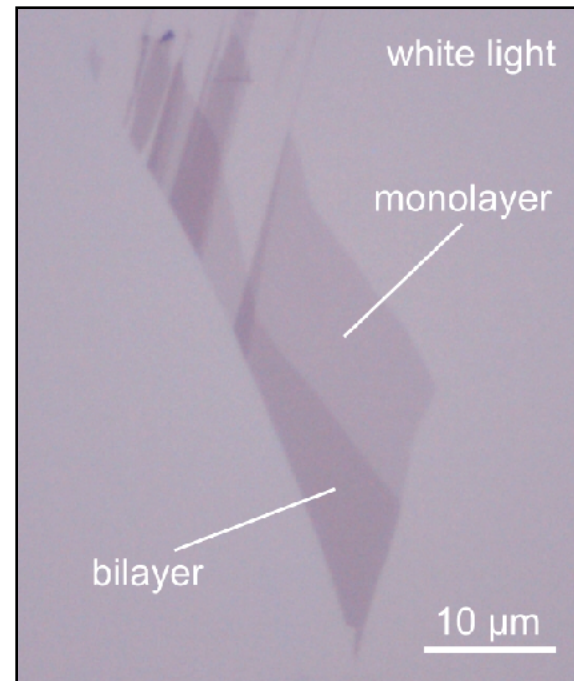
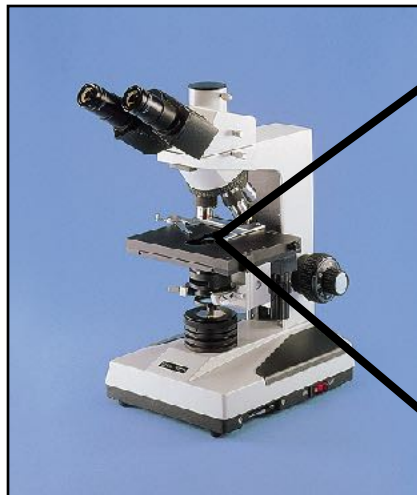
+



=

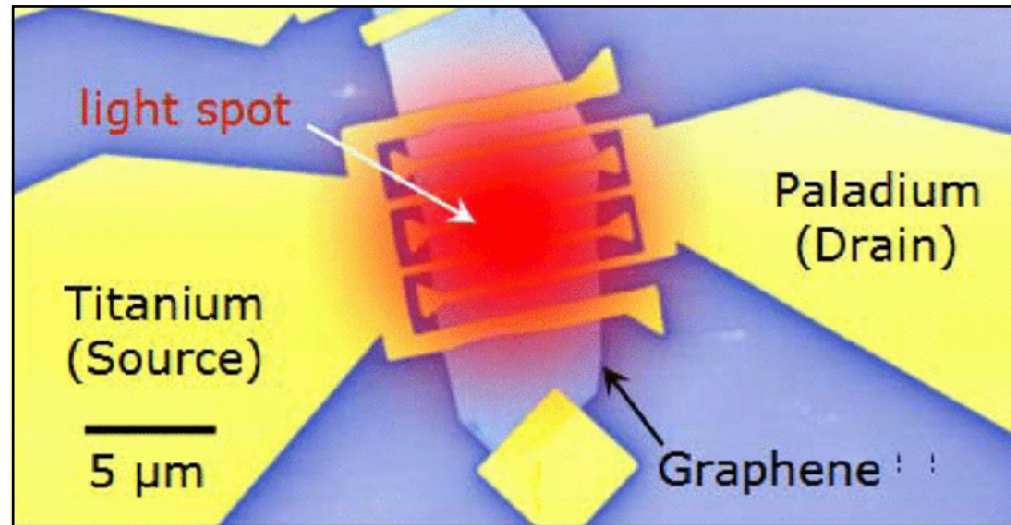


Step 2

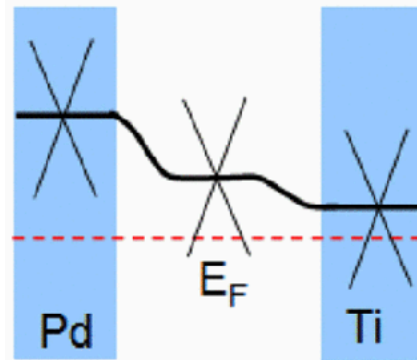




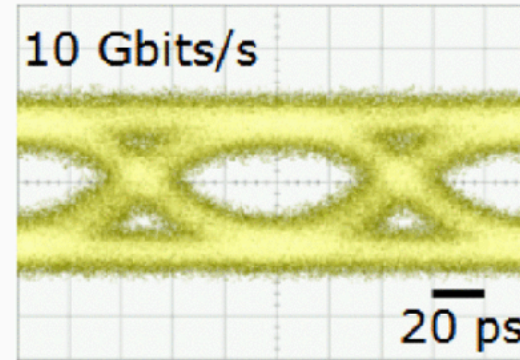
# Applications: sensitive, high-speed photodetectors



(a)

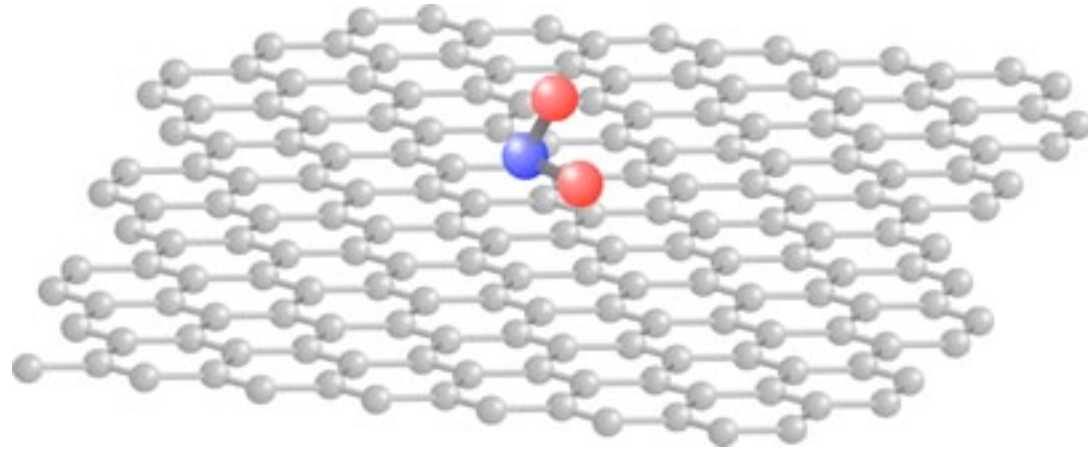


(b)



(c)

# Applications: adsorbed gas detection



Directly exposed surface

Conductivity highly sensitive to doping

# Applications: is carbon the new silicon?

High mobility (fast ops.)



Tunable carrier density

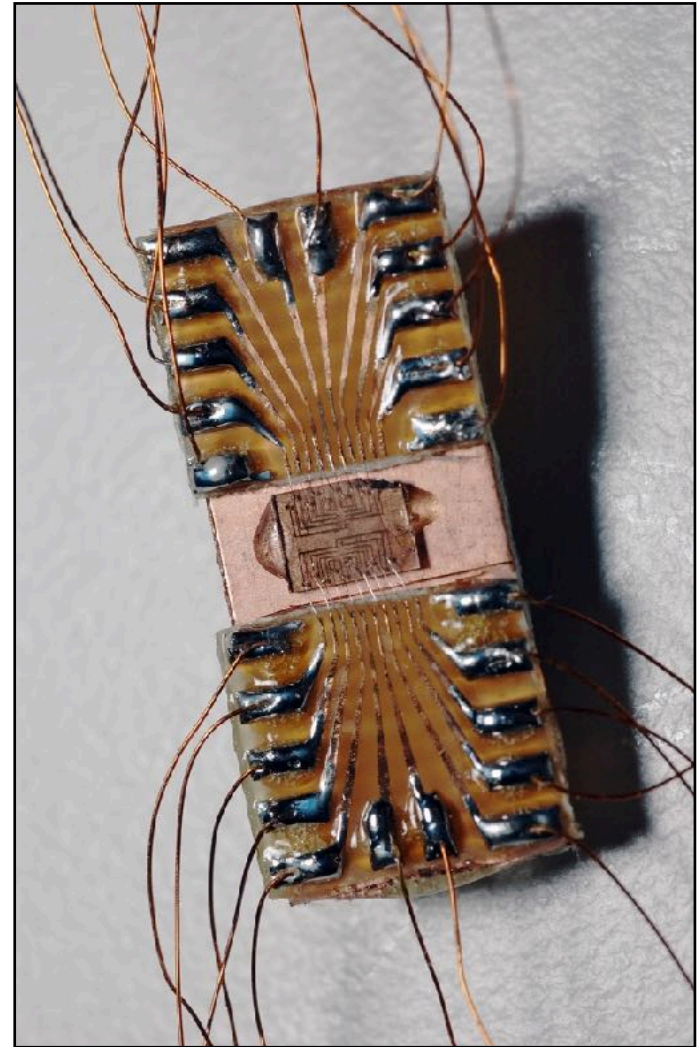


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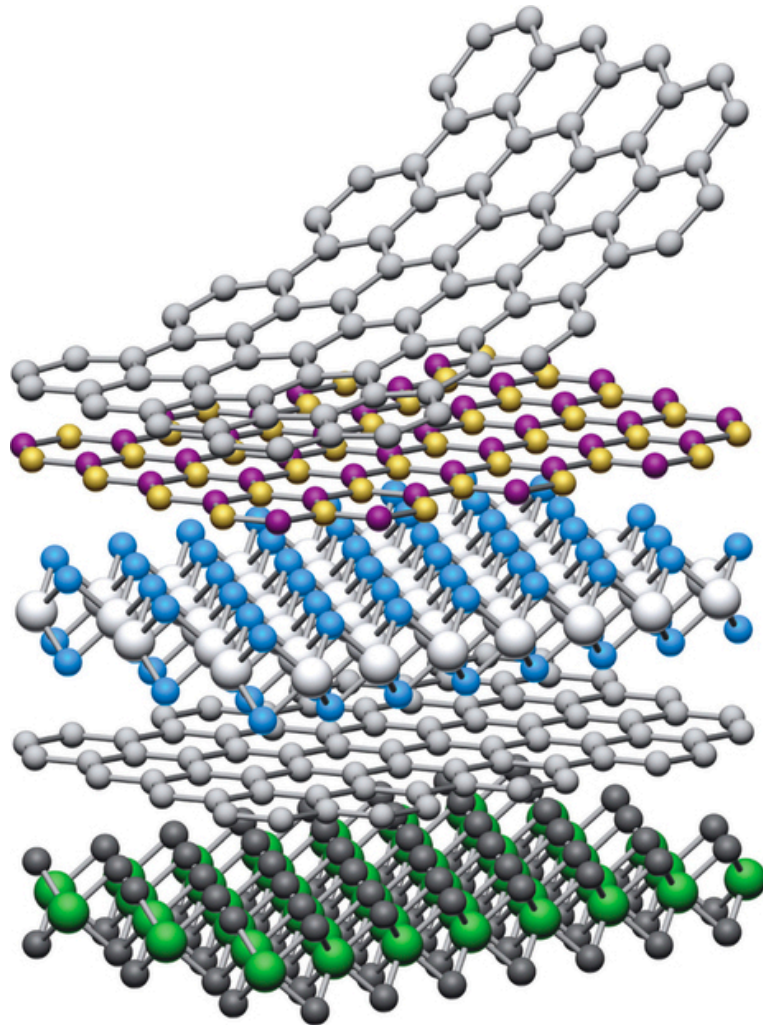
Small samples

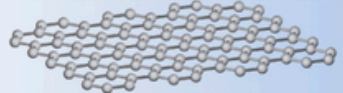

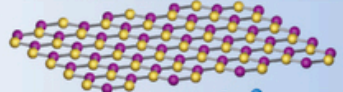
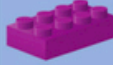
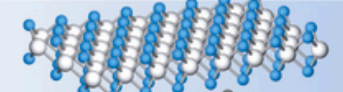

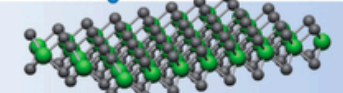

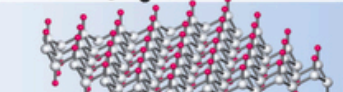



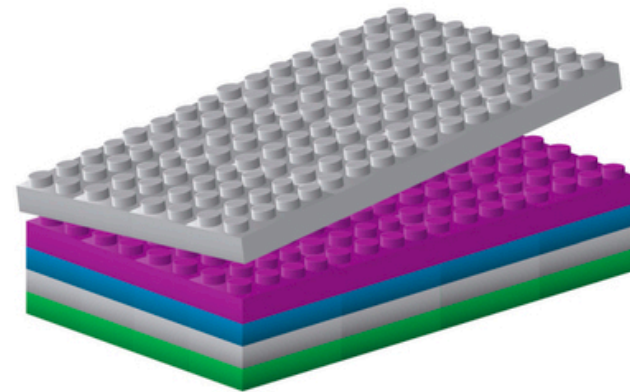
No band gap



# The future: hybrid materials built layer-by-layer



	Graphene	
	hBN	
	MoS <sub>2</sub>	
	WSe <sub>2</sub>	
	Fluorographene	





How can we use lasers, microwaves to *dynamically* control the behavior, properties of quantum systems?

Past



$\text{Pb} \rightarrow \text{Au}$

Present



$\text{GaAs} \rightarrow \text{HgTe?}$   
 $\rightarrow \dots ?$

# \$100M Question: Can a system governed by *quantum mechanical* laws compute better?

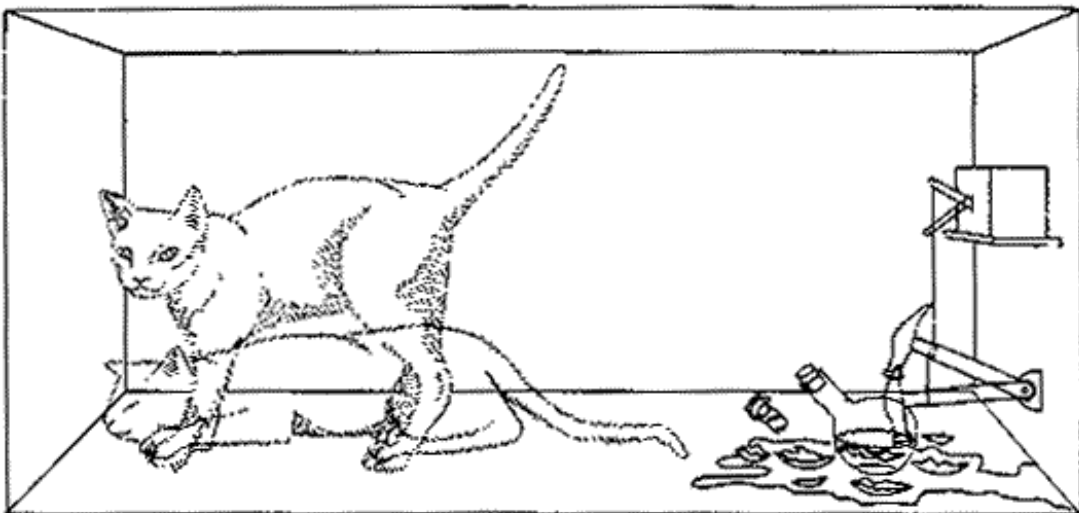
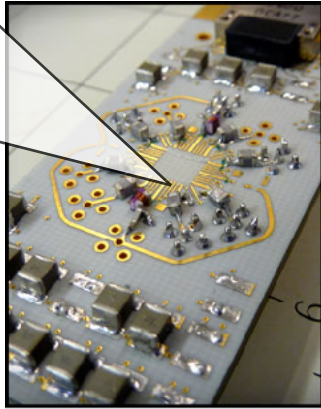


Image from: [www.upscale.utoronto.ca](http://www.upscale.utoronto.ca)



...

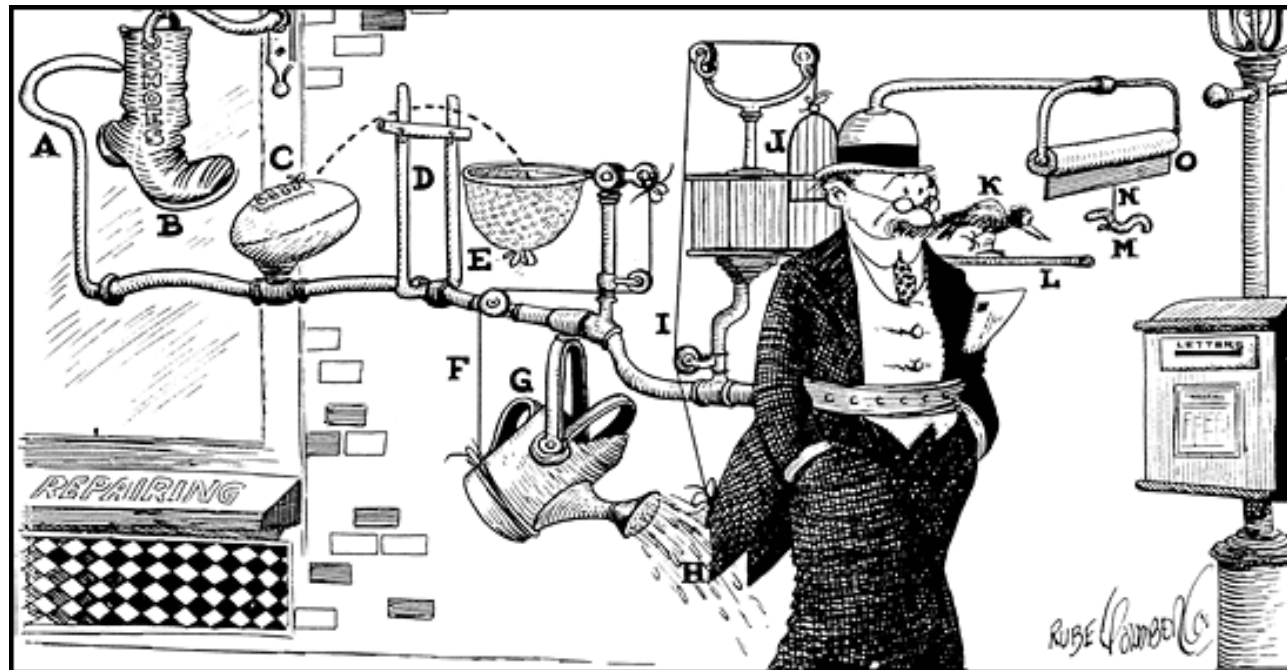
THIS SLIDE INTENTIONALLY LEFT BLANK

## Part II: Information is physical

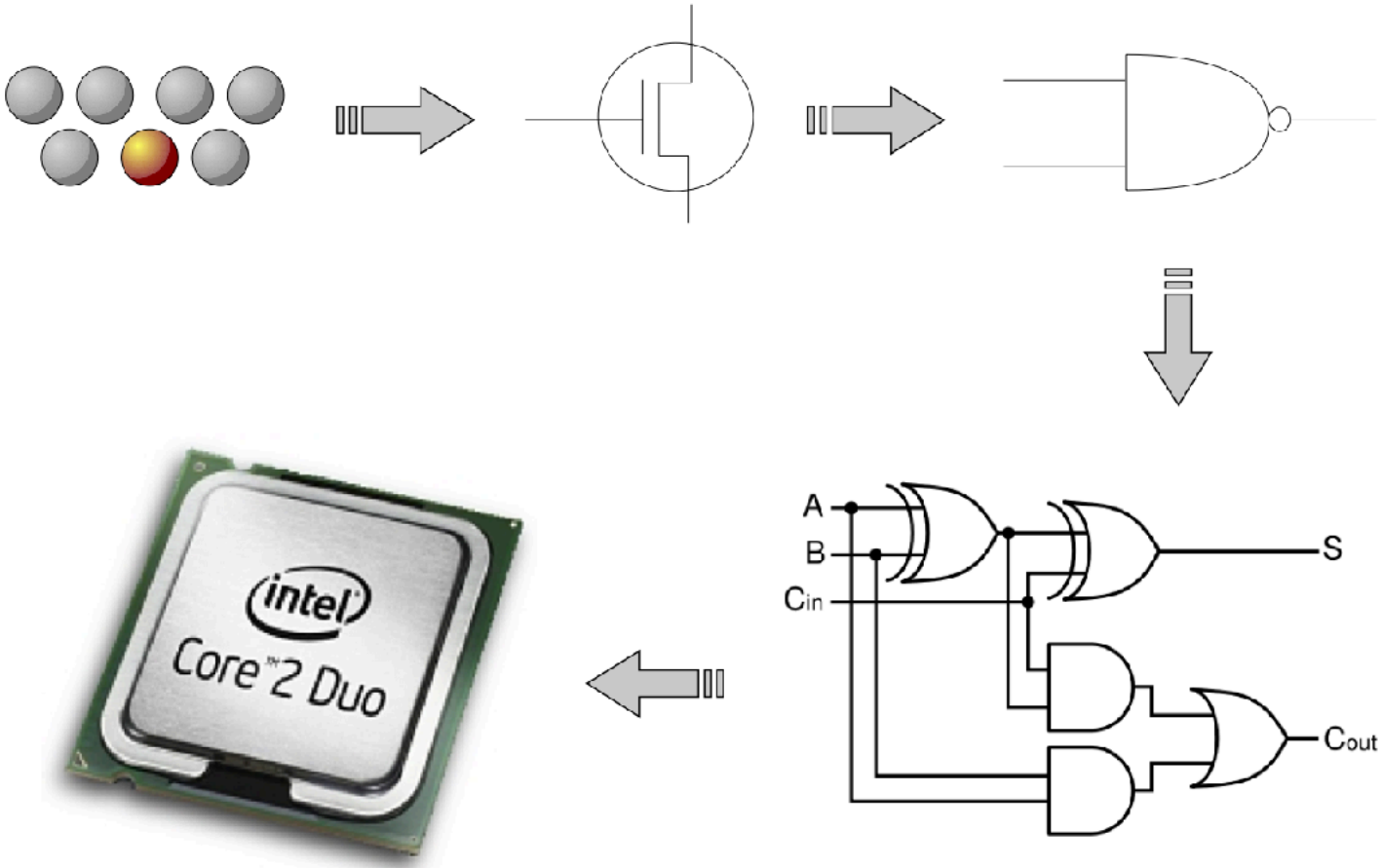
# Minimalist view of a (digital) computer

**Store information** (discretely) in state of physical system

**Control behavior** of system based on this information



# Transistor is the basic functional element in a digital processor



# Smaller, faster, lighter; underlying idea remains the same

several inches



1947



2.31 inches  
58.6 mm



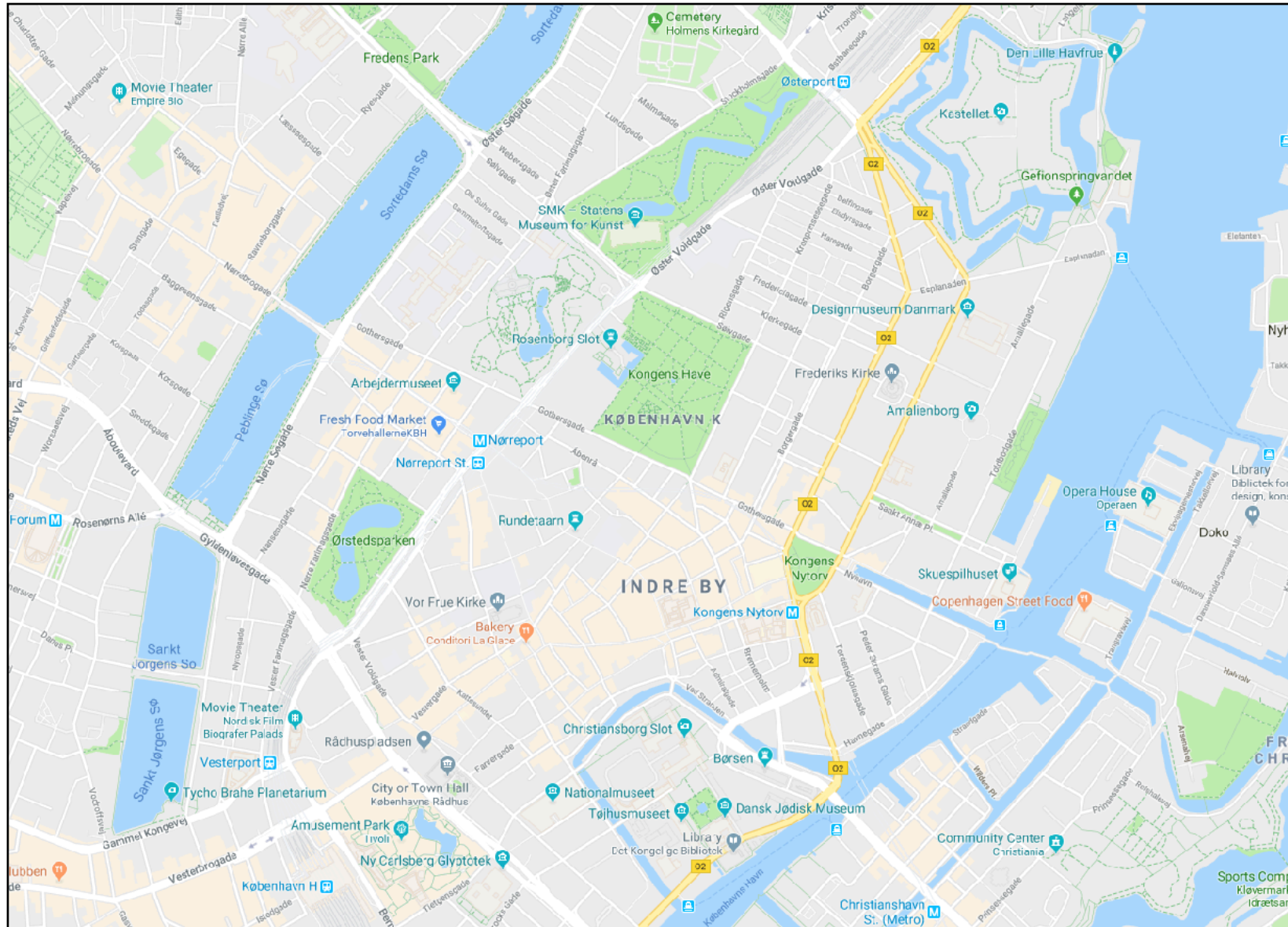
4.87 inches  
123.8 mm

Today

Question: how big would an iPhone be with original transistors?



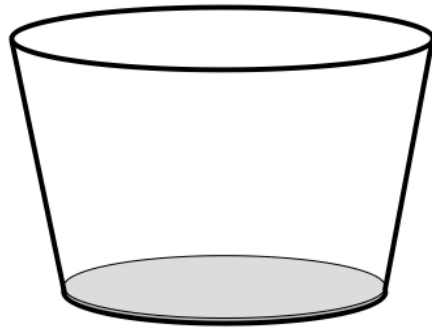
# Here's how far we've come:



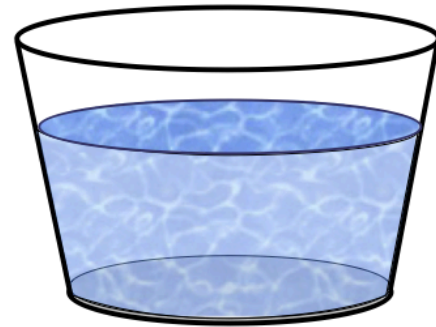
# Here's how far we've come:



# Mechanical analogy: how to store information with water

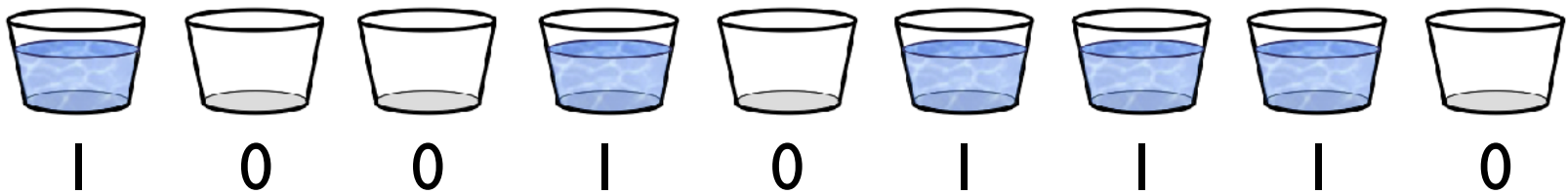


“0”



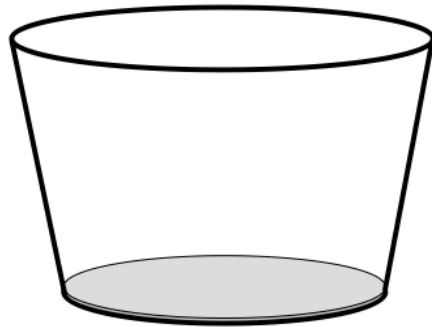
“1”

Example: store a number in binary

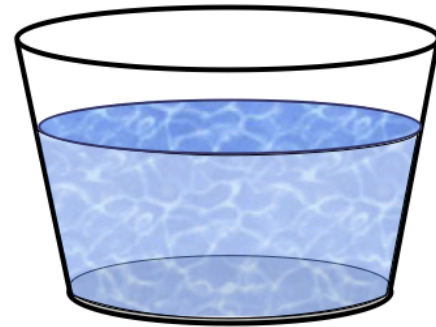




# Mechanical analogy: how to store information with water



“0”



“1”

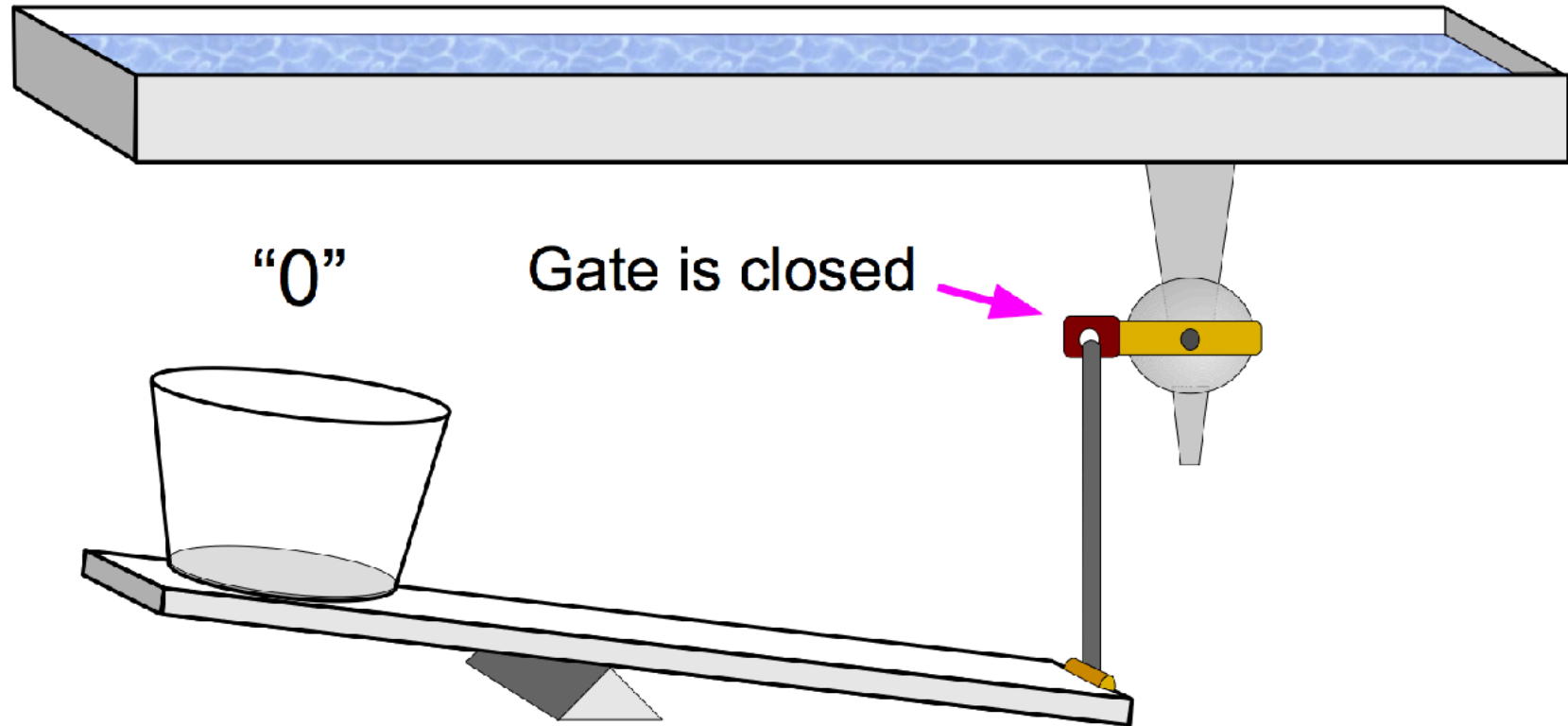
Example: store a number in binary



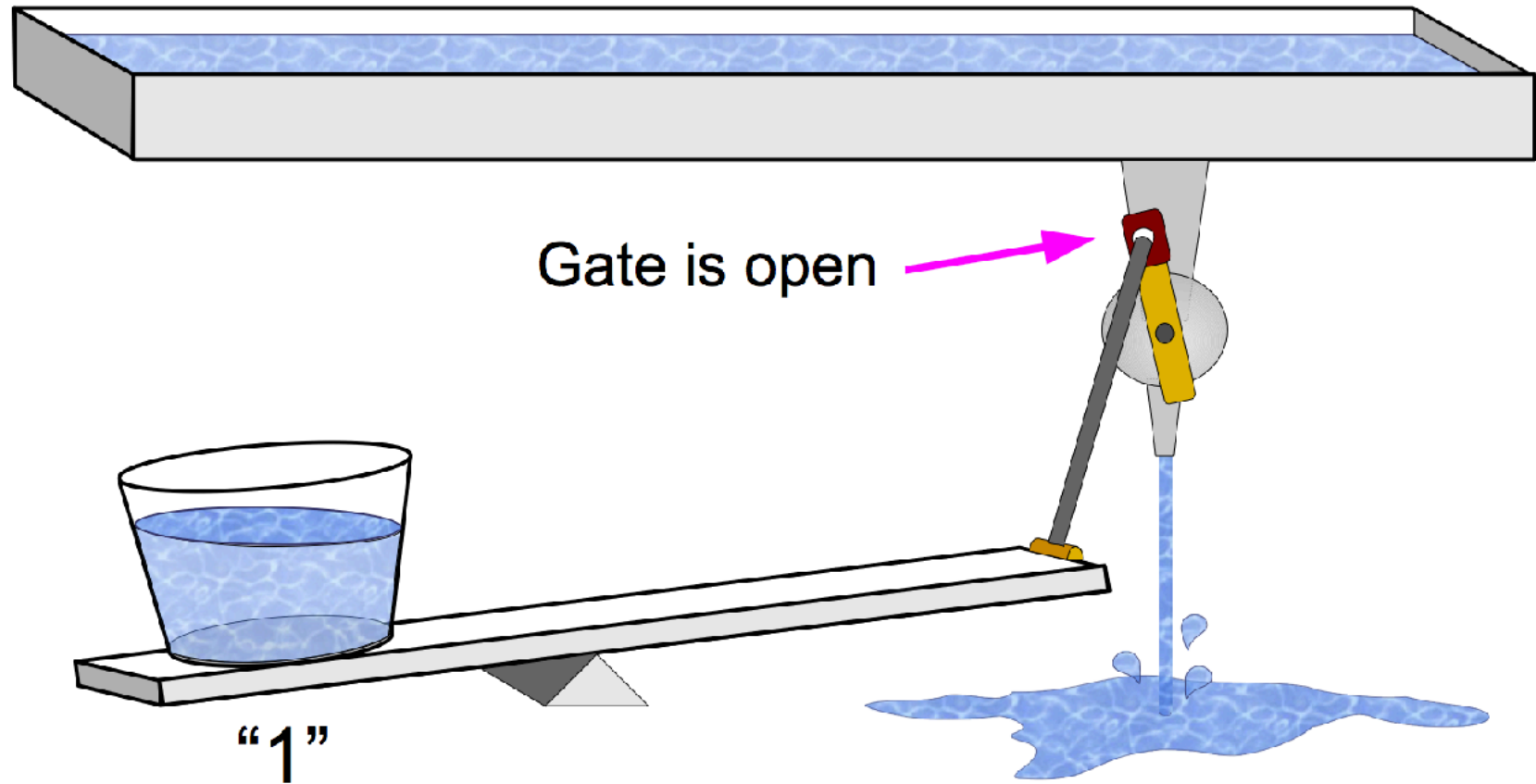
1 0 0 1 0 1 1 1 0

256 128 64 32 16 8 4 2 1 = 302

A “water transistor:” use buckets to control flow

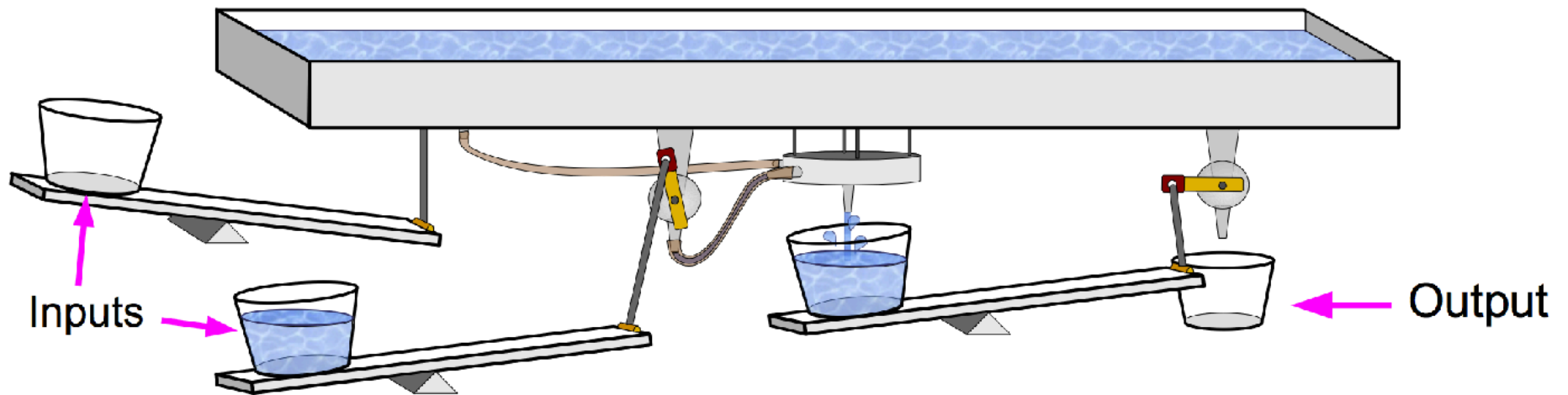


A “water transistor:” use buckets to control flow



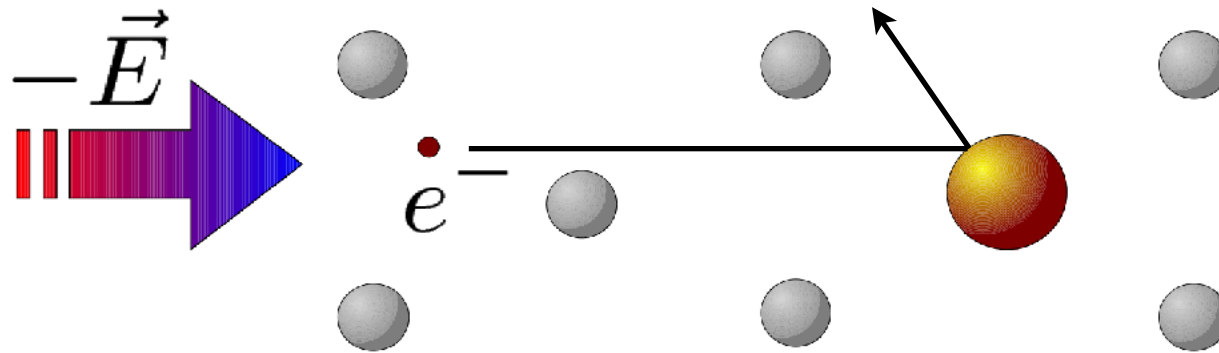
# Water-based digital logic (approximate NOR gate)

Filling of inputs determines output:



# Electrical transistor: use charge to control electrical channel

Conductivity expresses how easy/hard it is to make current flow



$$(\text{Conductivity}) = (\text{Carrier Density}) \cdot (\text{Mobility})$$

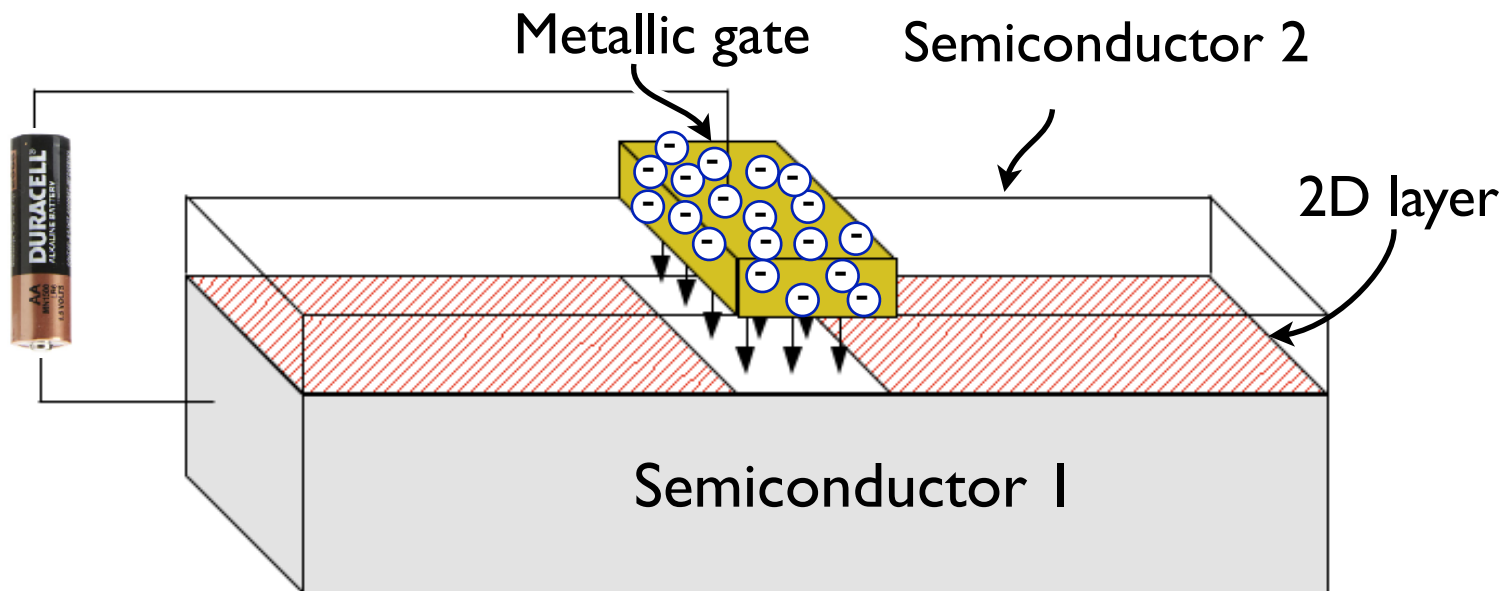
**Idea:** control conduction through channel by changing carrier density



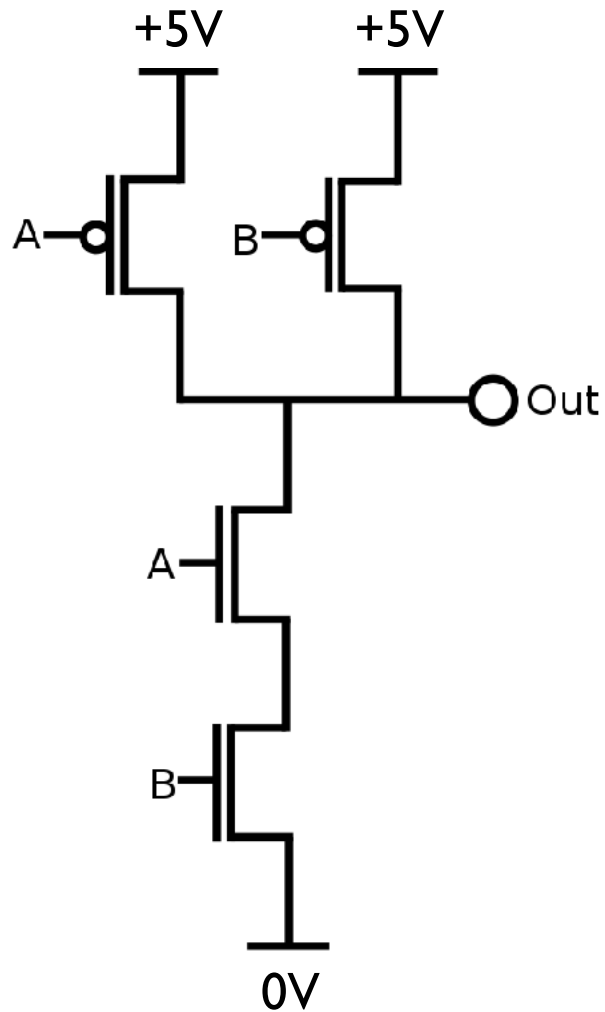
# Electrical transistor: use charge to control electrical channel

Electrons trapped at interface, move in 2D layer


Charge on gate controls electron density below




# Logic gate produced by connecting several transistors



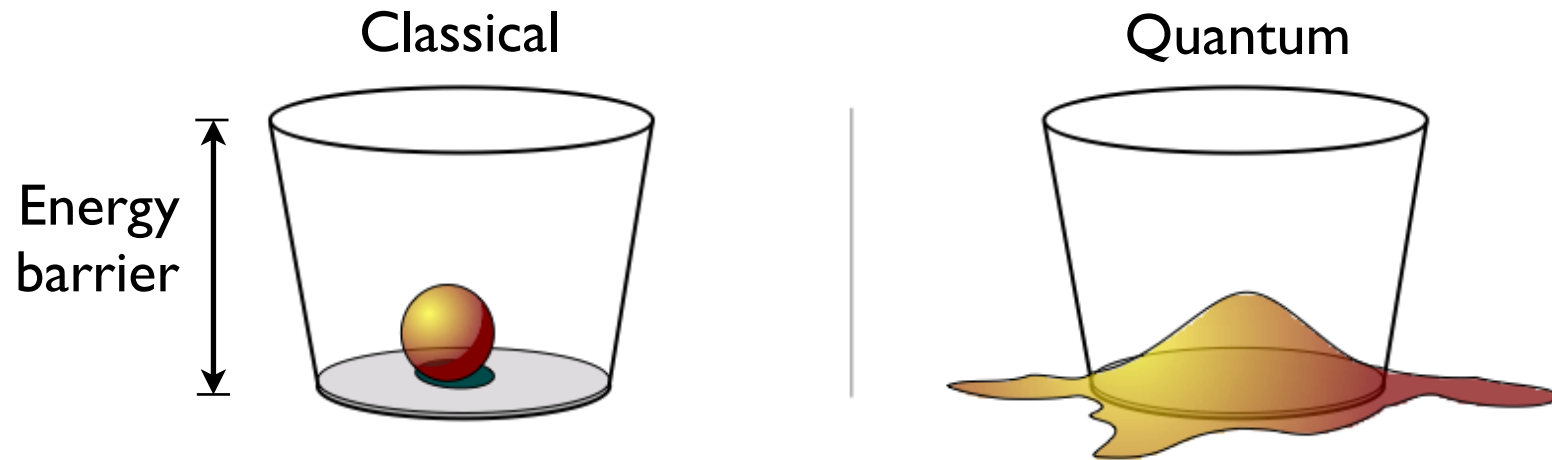
CMOS NAND gate  
(Wikipedia)

 low voltage (0): channel opened  
high voltage (1): channel blocked

 low voltage (0): channel blocked  
high voltage (1): channel opened

Now, make it smaller. What could go wrong?

# Quantum tunneling: “matter wave” cannot be fully trapped

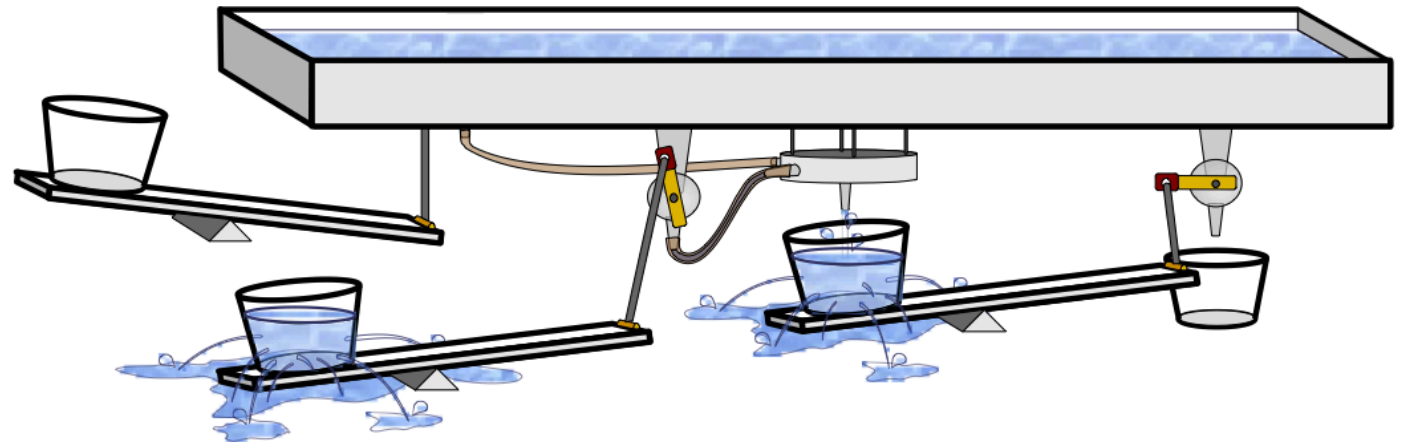


# Tunneling speeds up *exponentially* as barrier thickness shrinks

Smaller transistors leads to greater leakage, power consumption

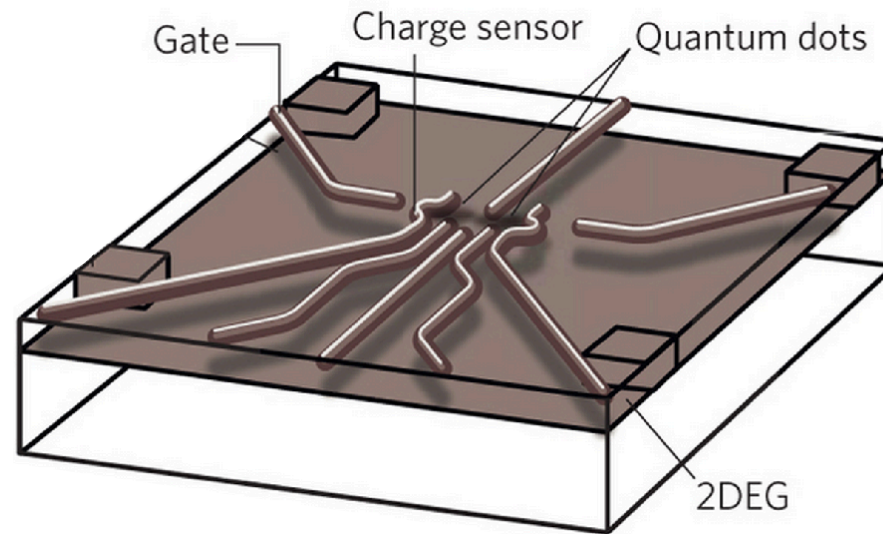
a) Bad for the **environment**

b) Excessive heating hinders further downsizing



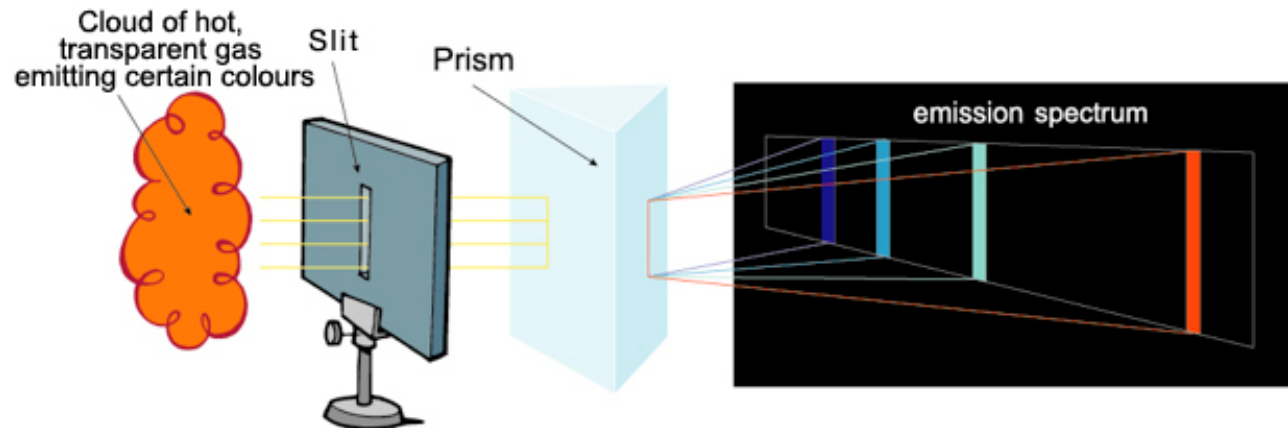
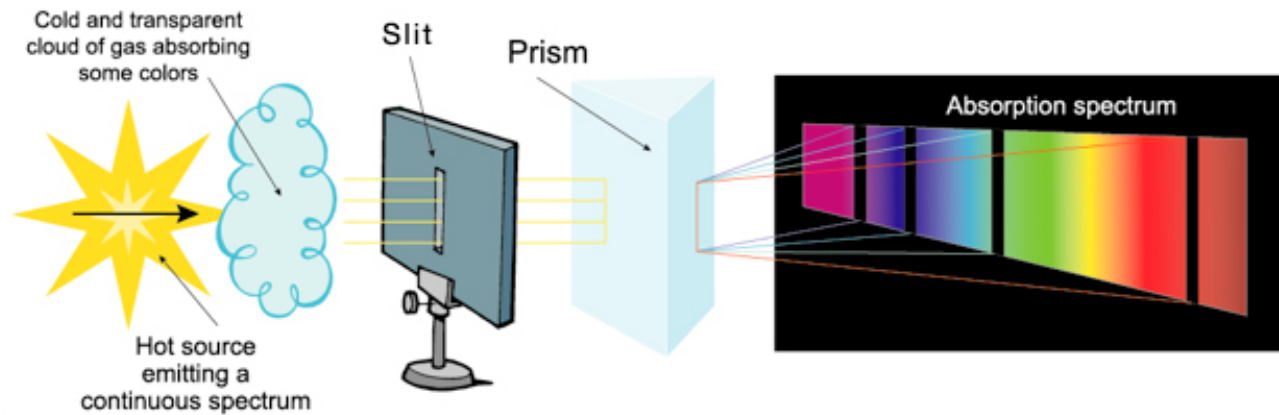


# Part III: *Quantum* nanoelectronic devices



Nature Materials **12**, 494 (2013)

# Early 1900s: energy absorbed/emitted in discrete amounts



# A quantum dot is an “artificial atom”

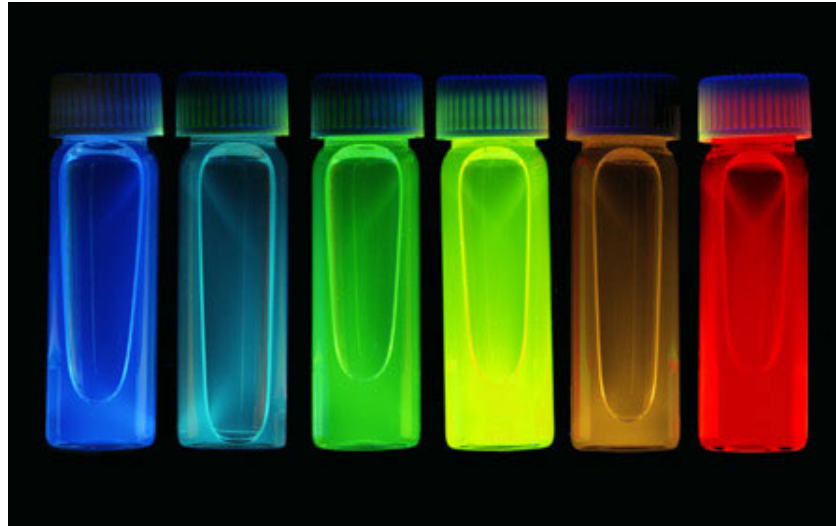
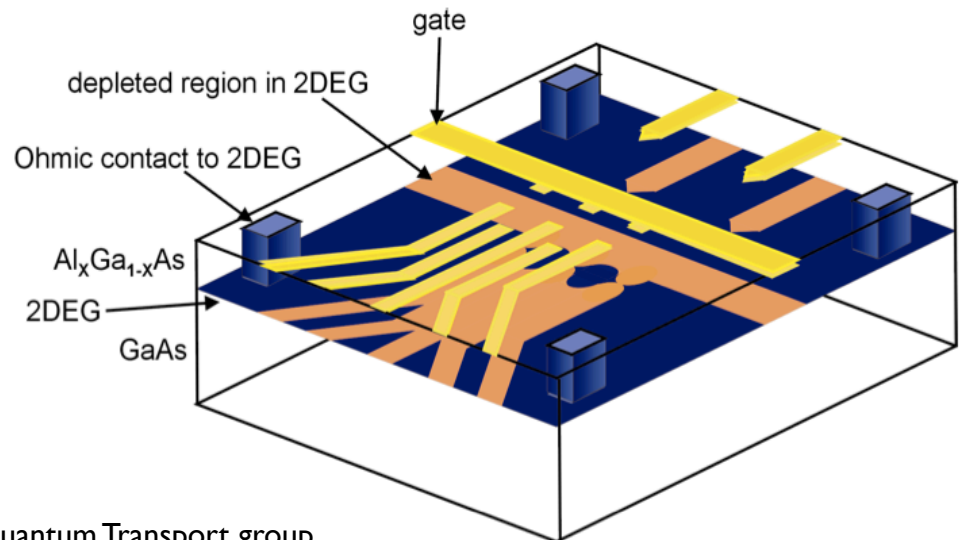
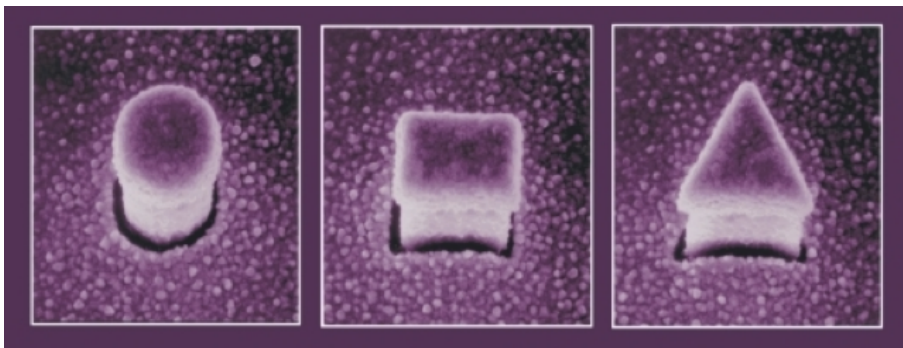


Photo by Felice Frankel, MIT ([web.mit.edu](http://web.mit.edu))



Images from TU Delft Quantum Transport group

Confinement reduces wavelength, increases energy scale

Analogy:

Smaller drum, higher frequency



$$(\text{energy}) = (\text{Planck's Constant}) \cdot (\text{frequency})$$

For 100 nm dot, temperature must be close to 1 Kelvin

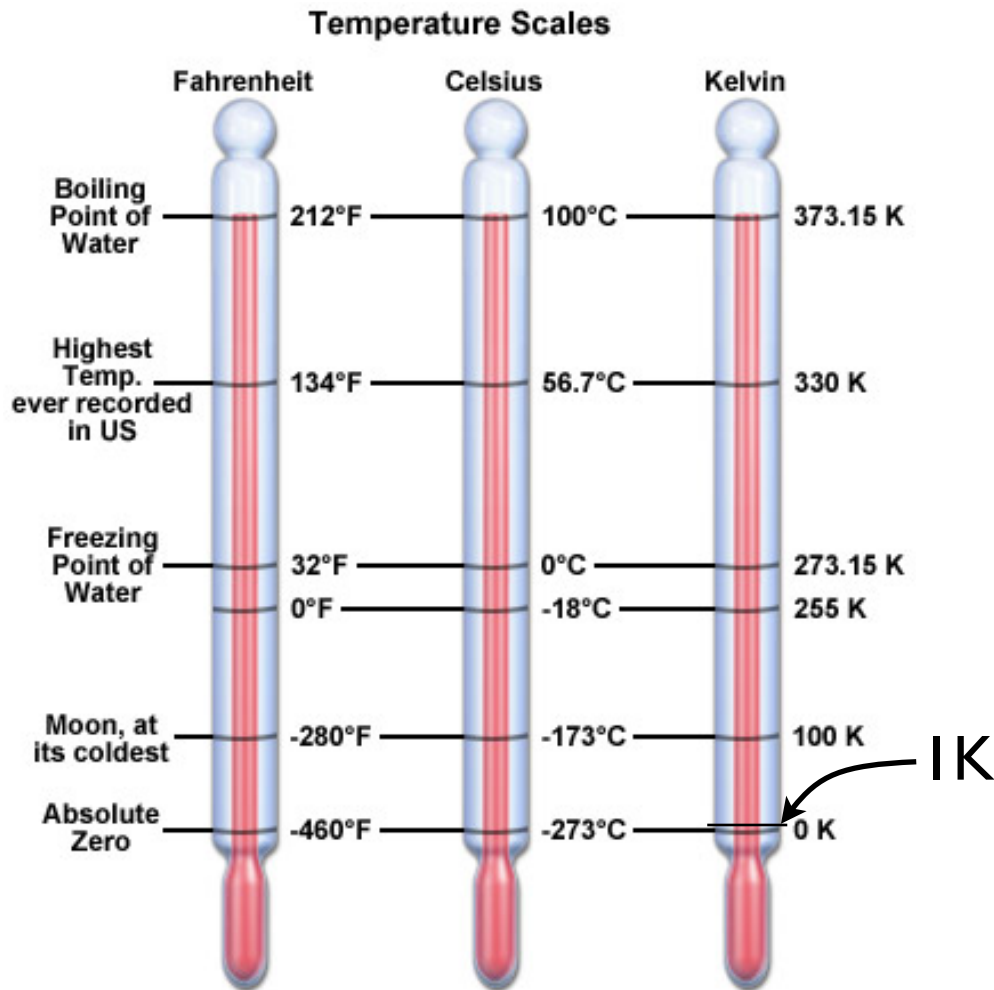


Image from [www.magnet.fsu.edu](http://www.magnet.fsu.edu)

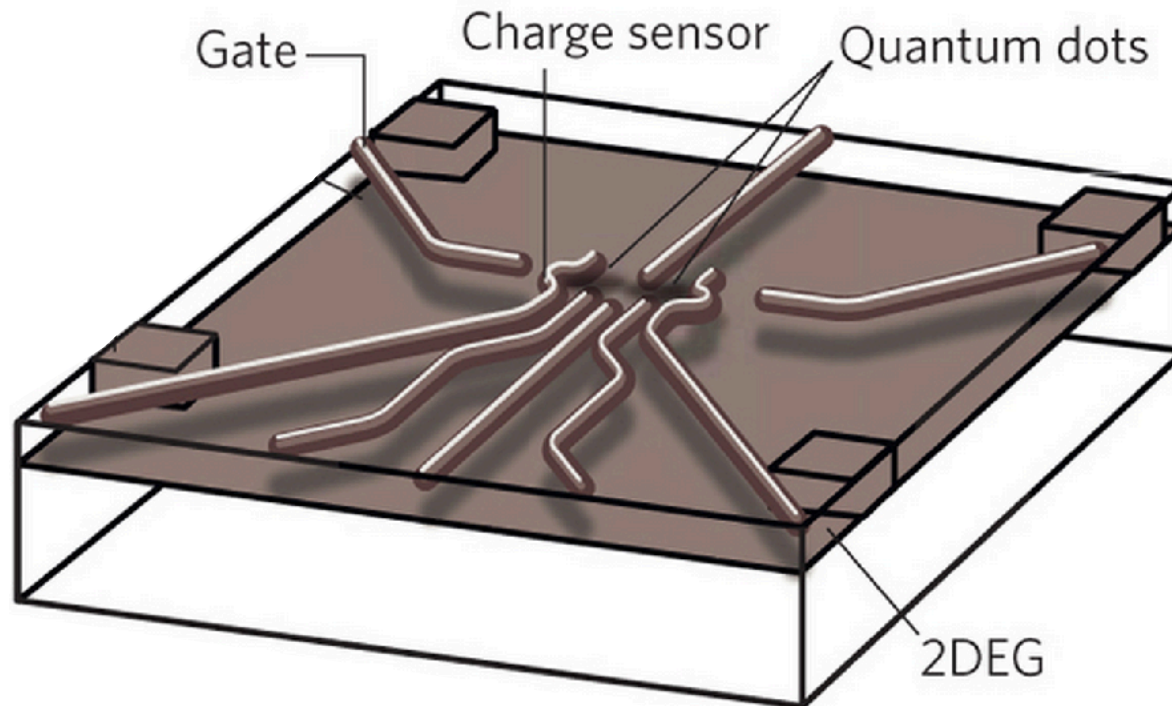
How big is 100 nm?

200 atoms side-by-side

1/100 size of red blood cell

1/1000 width of a human hair

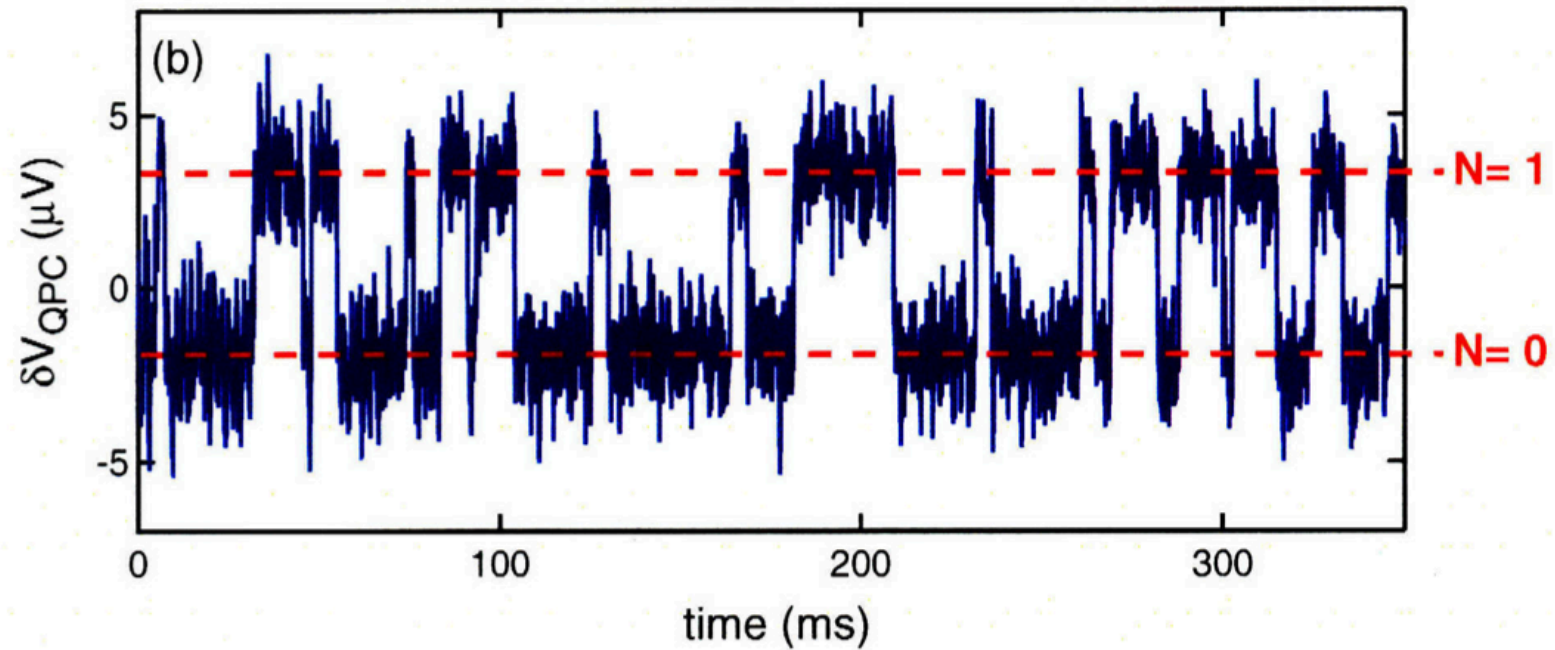
Use gates to deplete 2D layer, trap electrons in small puddles



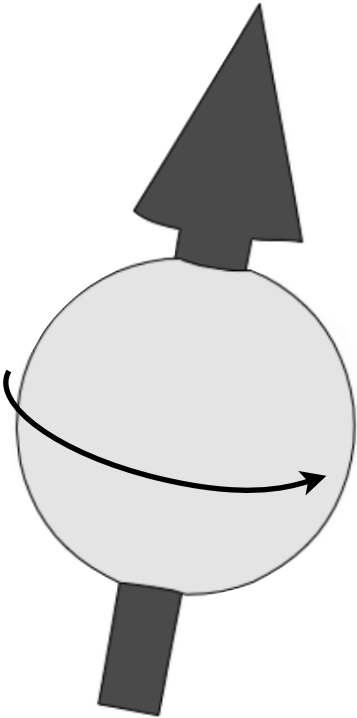
Nature Materials **12**, 494 (2013)



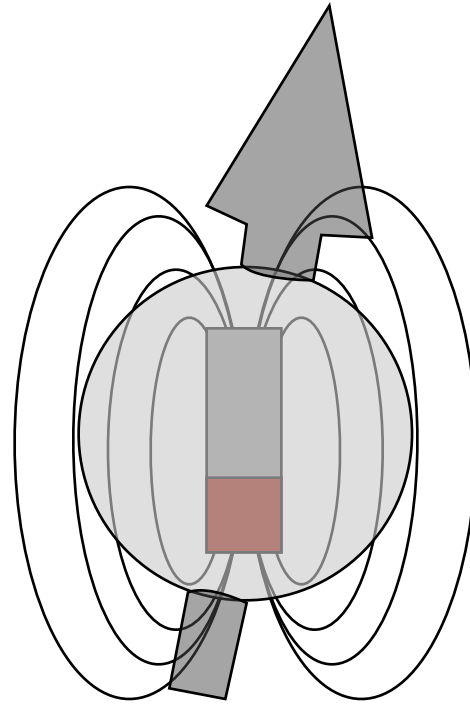
# Single electron tunneling in and out of device is sensed directly



Besides mass and charge, electron also has “spin”



A spin is like a tiny magnet,



which prefers to align with a magnetic field

State of spin is a *superposition* of only two choices: up or down

“Down” spin moves to stronger field

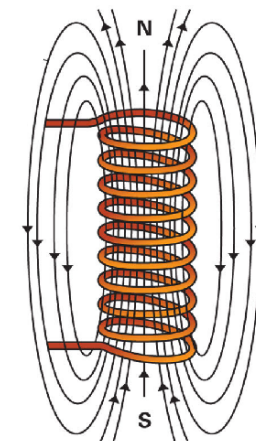
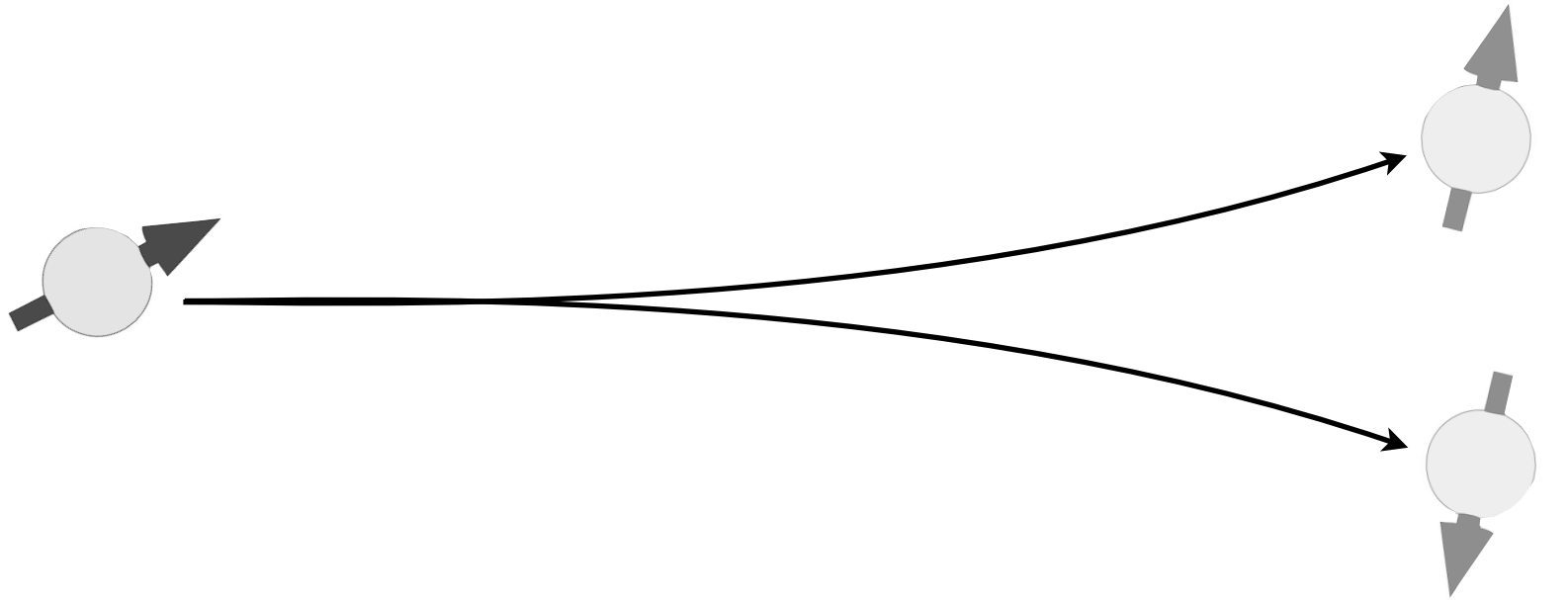


Image from ece.neu.edu

A bit also has two choices (0 or 1); this is a *quantum* bit

Classical bit



Bit is on (1) **or** off (0)

Quantum bit



Qubit can be on (1) **AND** off (0)

# The spin of a single electron in a quantum dot is a “qubit”

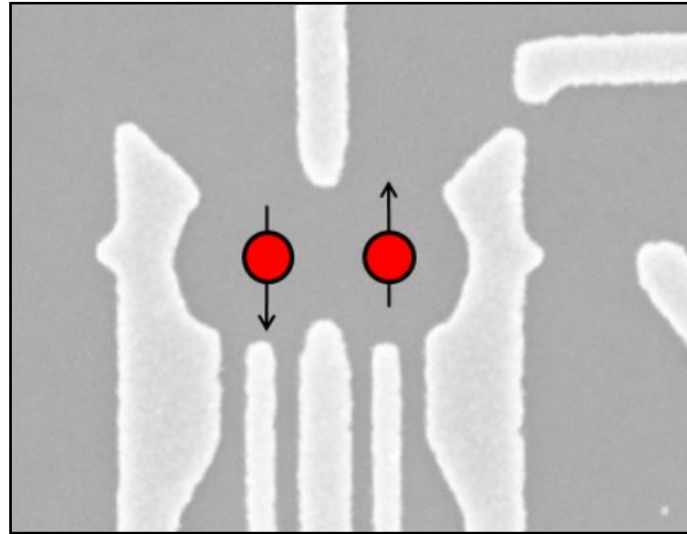


Image from Yacoby group, Harvard

$$\begin{array}{l} \downarrow = 0 \\ \uparrow = 1 \end{array}$$

Original proposal:

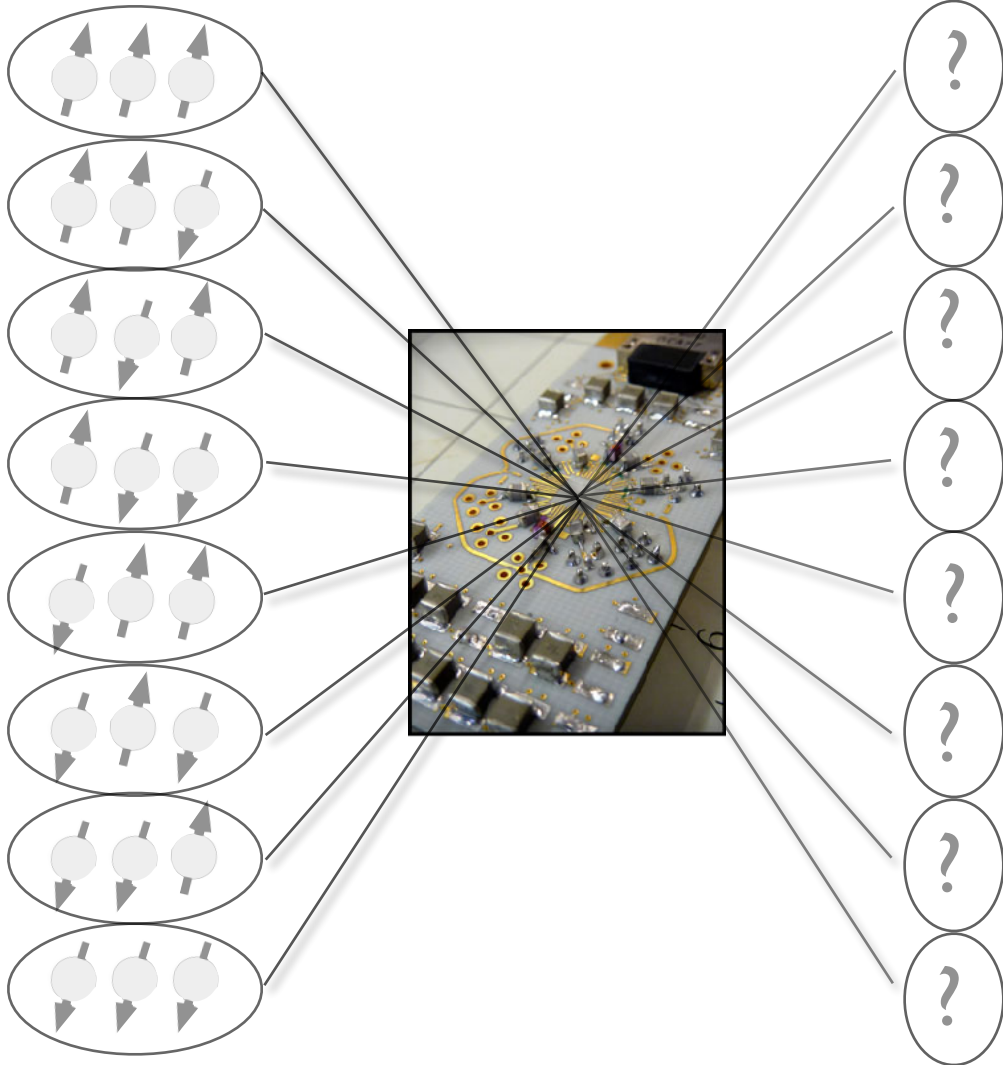
D. Loss and D. P. DiVincenzo, Phys. Rev. A **57**, 120 (1998).

# Quantum parallelism: use superposition to run all inputs at once

Each case run one by one

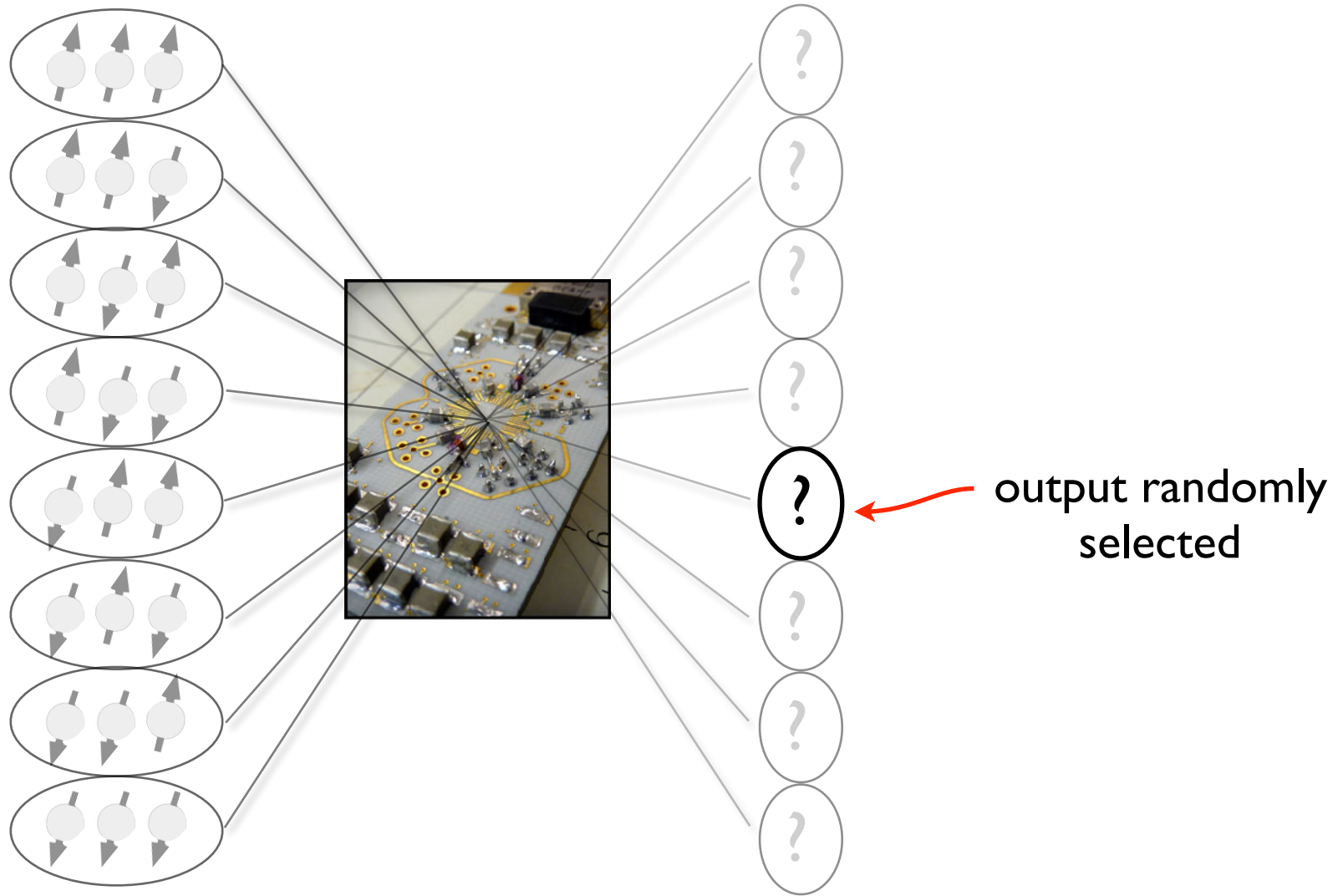


Quantum computer runs all at once

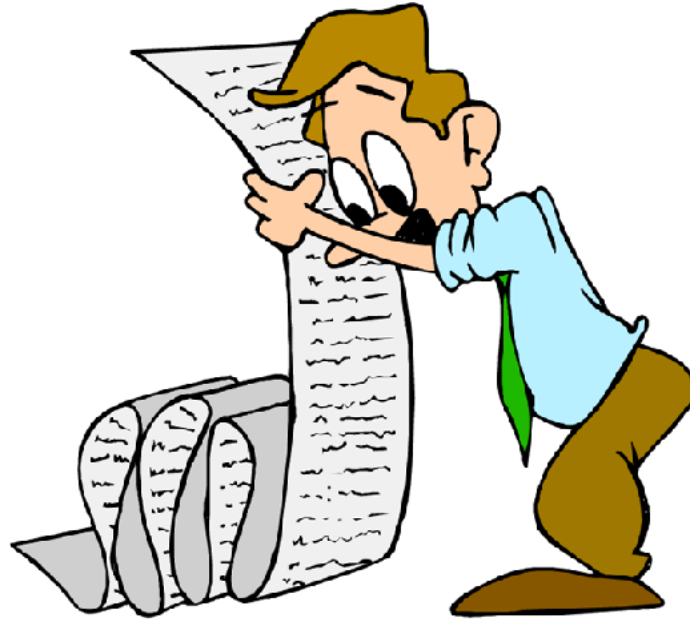




On any run, only get to see one of the possible answers



# Clever tricks use interference to amplify desired output



Example: Highly efficient searching possible

“Big Data” applications

Sociology

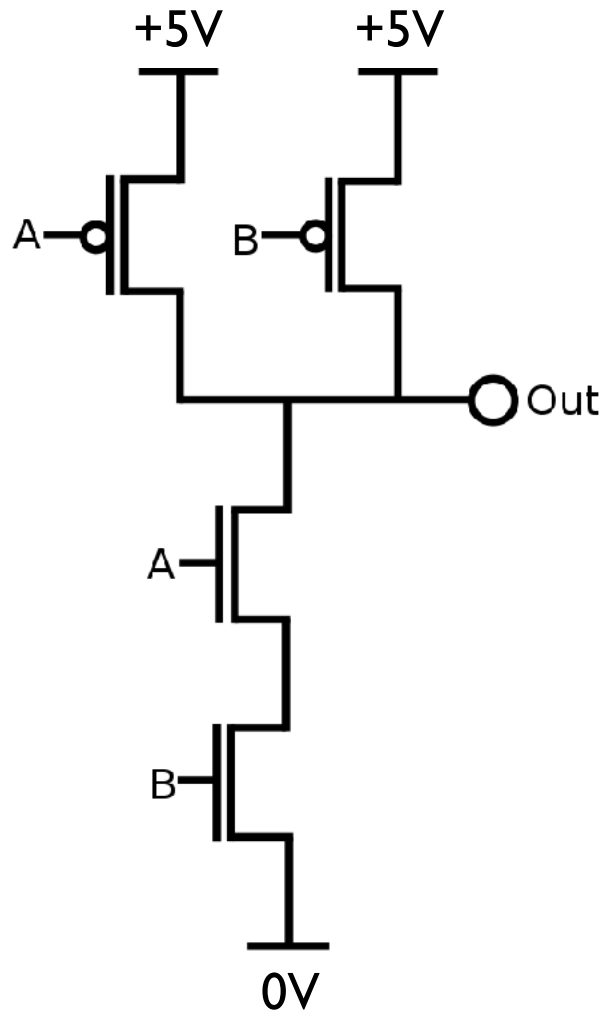
Genomics

Economics

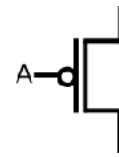
...

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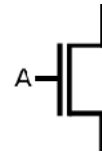
# Logic gate produced by connecting several transistors



CMOS NAND gate  
(Wikipedia)



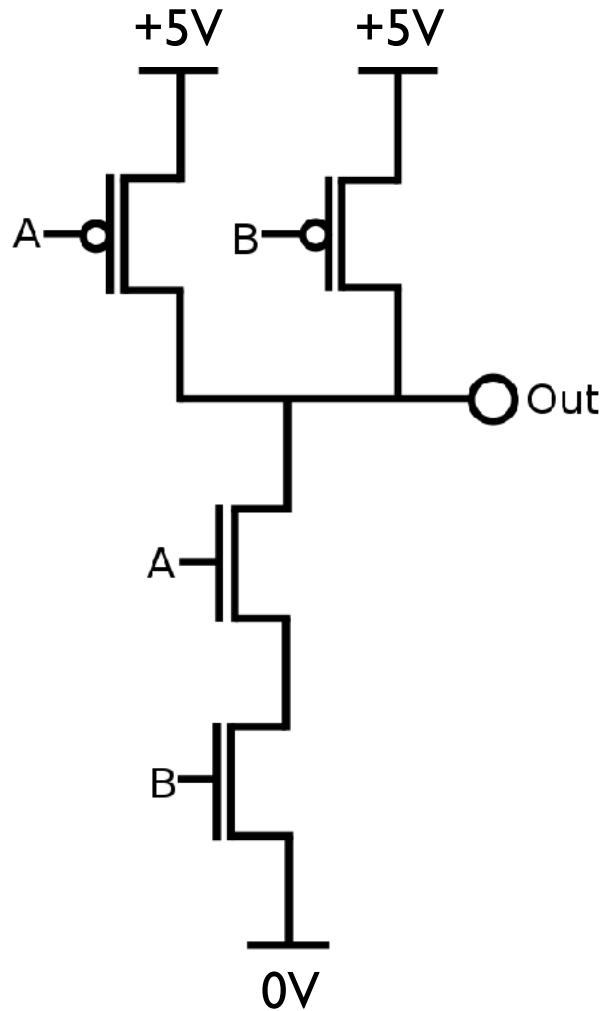
low voltage (0): channel opened  
high voltage (1): channel blocked




low voltage (0): channel blocked  
high voltage (1): channel opened


A	B	Out
<b>0</b>	<b>0</b>	

# Logic gate produced by connecting several transistors



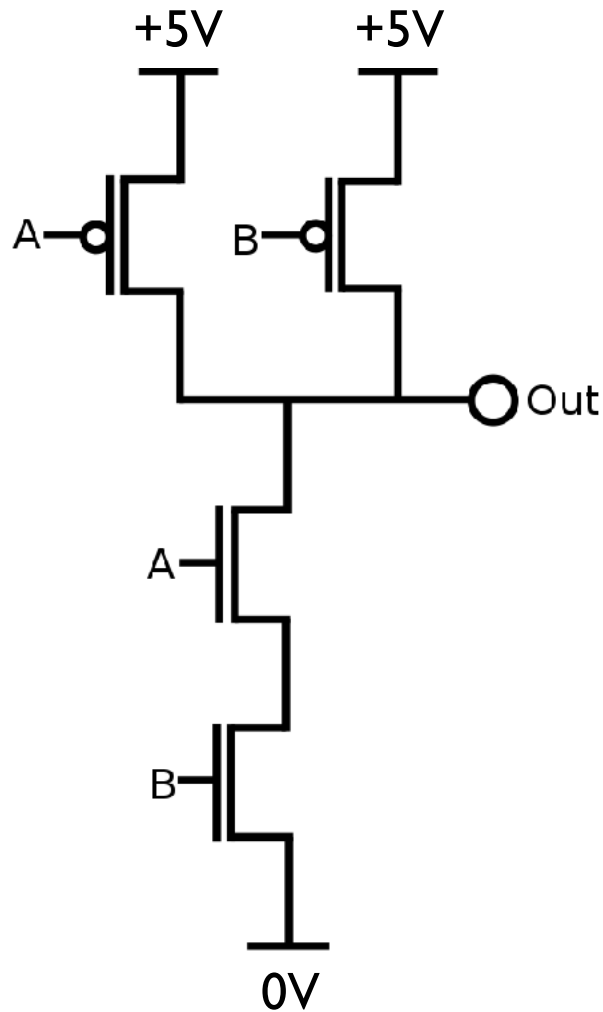
CMOS NAND gate  
(Wikipedia)

 low voltage (0): channel opened  
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 low voltage (0): channel blocked  
high voltage (1): channel opened


A	B	Out
<b>0</b>	<b>0</b>	+5V (1)

# Logic gate produced by connecting several transistors



CMOS NAND gate  
(Wikipedia)

 low voltage (0): channel opened  
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 low voltage (0): channel blocked  
high voltage (1): channel opened

A	B	Out
0	0	+5V (1)
0	1	+5V (1)
1	0	+5V (1)
1	1	0V (0)